

BPM electrode and high power feedthrough –Special topics in wideband feedthrough–

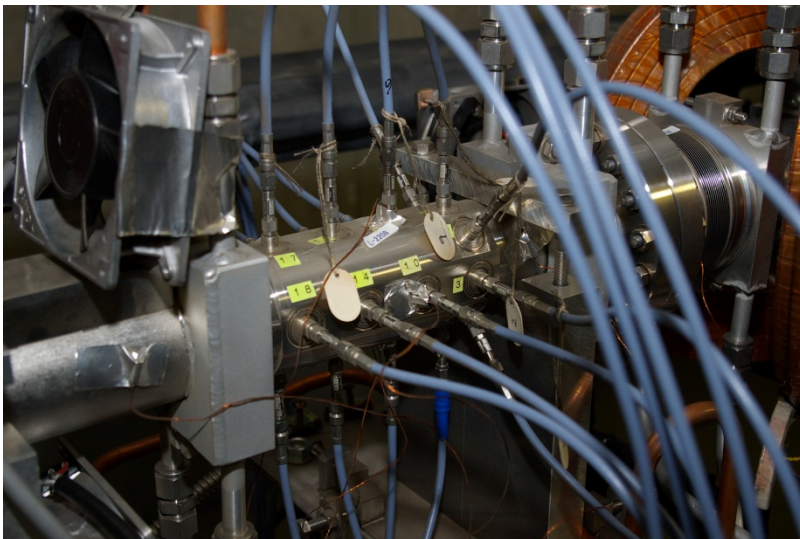
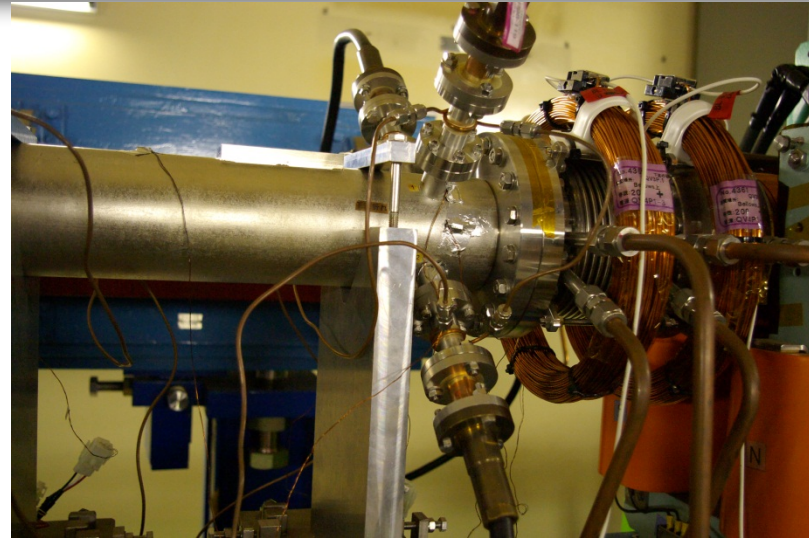
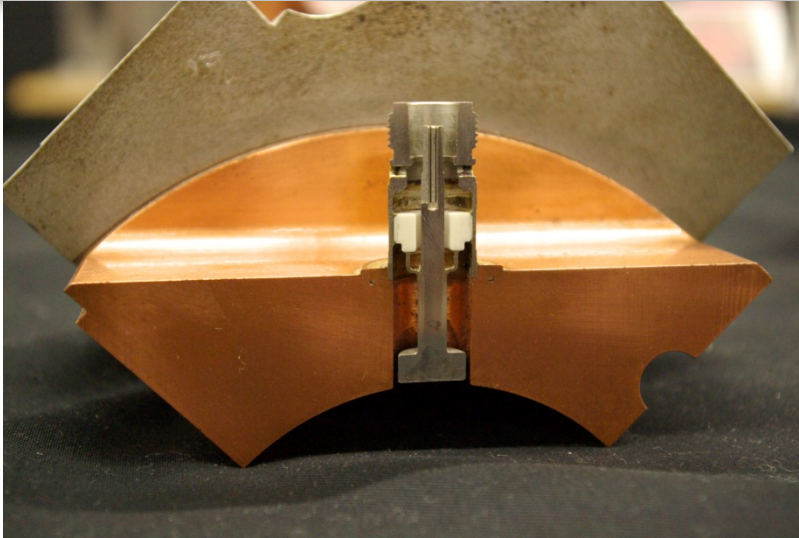
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Introduction

- **Beam runs in vacuum chambers (mostly) made of good-conducting metal.**
 - Vacuum chambers shield (fast) electro-magnetic wave from / to the beam.
 - Need some kind of “Feedthrough” to get / feed the electro-magnetic signal from / to beam.
- **Wideband coaxial feedthrough**
 - Button-type electrode
 - Stripline kicker / monitor
 - Plate-type position monitor
 - Ion (or electron cloud) clearing electrode

Feedthrough



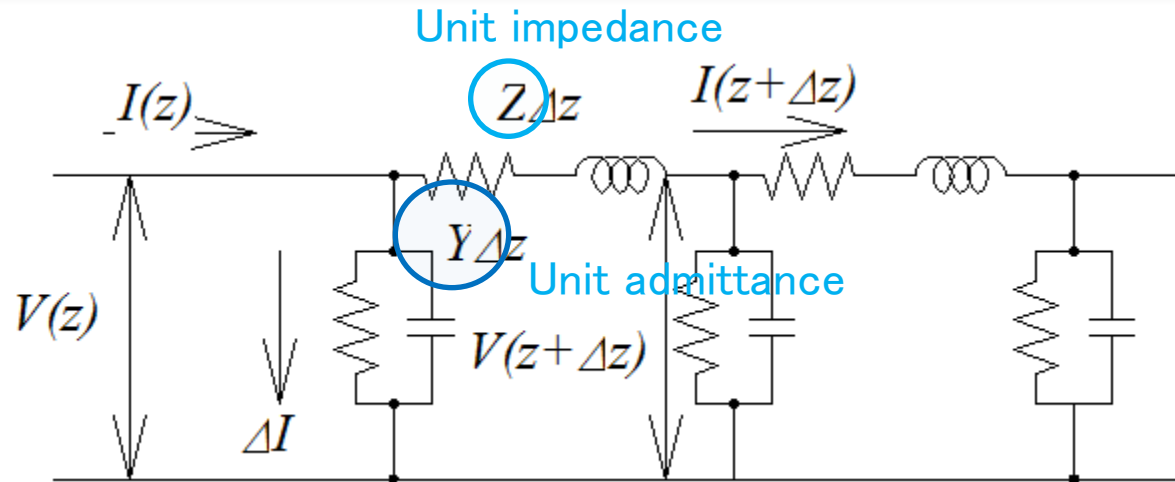
Need to consider..

- **Specification of the feedthrough**
 - Structure
 - Total size
 - Kind of RF connector, vacuum structure...
 - Mechanical (and heating) toughness
 - Frequency range, allowed SWR, reflection..
 - Power range
 - Beam induced power
 - Supplied power from outside
 - allowed (V)SWR

In this tutorial

- **Review of transmission line theory**
 - S-Parameter, (V)SWR
 - Time domain behavior (TDR)
- **Frequency-domain simulation**
 - Ansys HFSS
- **Time-domain simulation**
 - GdfidL
- **Design, evaluation of the button electrodes**
- **Design, evaluation of the high-power feedthroughs**
- **Summary**

Circuit representation of a uniform transmission line



$$\Delta V = -IZ\Delta z$$

$$\Delta I = -VY\Delta z$$

$$\frac{dV}{dz} = -IZ$$

$$\frac{dI}{dz} = -VY$$

$$\frac{d^2V}{dz^2} = \gamma^2 V, \frac{d^2I}{dz^2} = \gamma^2 I$$

$$\gamma^2 = ZY$$

Transmission line (cont.)

■ Solution

$$V = V_1 e^{-\gamma z} + V_2 e^{\gamma z}$$

$$= V_1 e^{(j\omega t - \gamma z)} + V_2 e^{(j\omega t + \gamma z)}$$

■ Normal transmission line

Resistance Inductance

$$Z = R + jL\omega$$

$$Y = G + jC\omega$$

Parallel
conductance

Capacitance

$$\gamma = (LC\omega^2)^{\frac{1}{2}} \left[1 - \frac{RG}{LC\omega^2} - j \left(\frac{G}{C\omega} + \frac{R}{L\omega} \right) \right]^{\frac{1}{2}}$$

$$\approx j\omega\sqrt{LC} \left[1 - j \left(\frac{G}{C\omega} + \frac{R}{L\omega} \right) \right]^{\frac{1}{2}}$$

$$\approx j\omega\sqrt{LC} \left(1 - j \frac{R}{2L\omega} \right)$$

Propagation constant

$$\gamma = \alpha + j\beta$$

$$\alpha = \frac{R}{2} \sqrt{\frac{C}{L}}, \beta = \omega \sqrt{LC}$$

$$V = V_1 e^{j(\omega t - \beta z)} e^{-\alpha z} + V_2 e^{j(\omega t + \beta z)} e^{\alpha z}$$

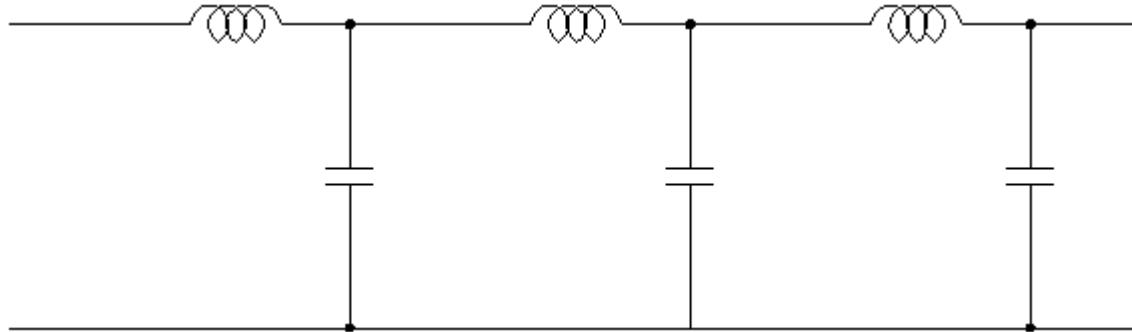
- **Phase velocity**

$$v_p = \frac{dz}{dt} = \frac{\omega}{\beta} = \frac{1}{\sqrt{LC}}$$

- **If phase velocity = group velocity**

$$\beta = \frac{2\pi f}{f\lambda} = \frac{2\pi}{\lambda}$$

Loss less line



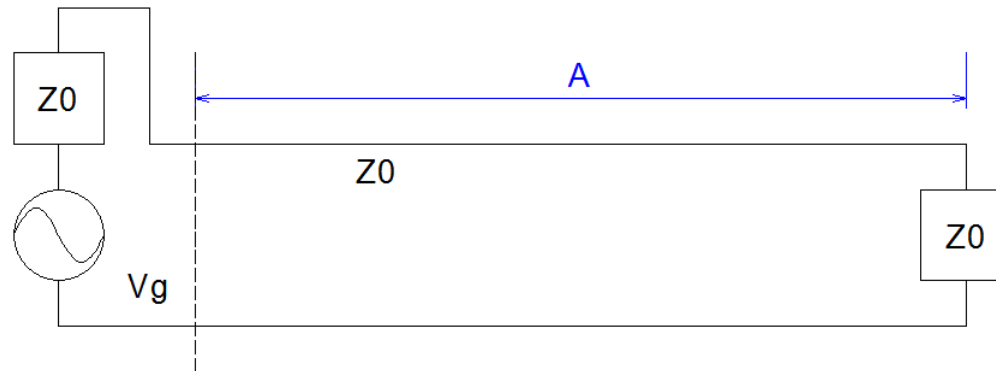
$$V = V_1 e^{-j\beta z} + V_2 e^{j\beta z}$$

$$I = \frac{1}{Z_0} (V_1 e^{-j\beta z} - V_2 e^{j\beta z})$$

$$Z_0 = \frac{Z}{\gamma} = \sqrt{\frac{L}{C}}$$

$$\beta = \omega \sqrt{LC}$$

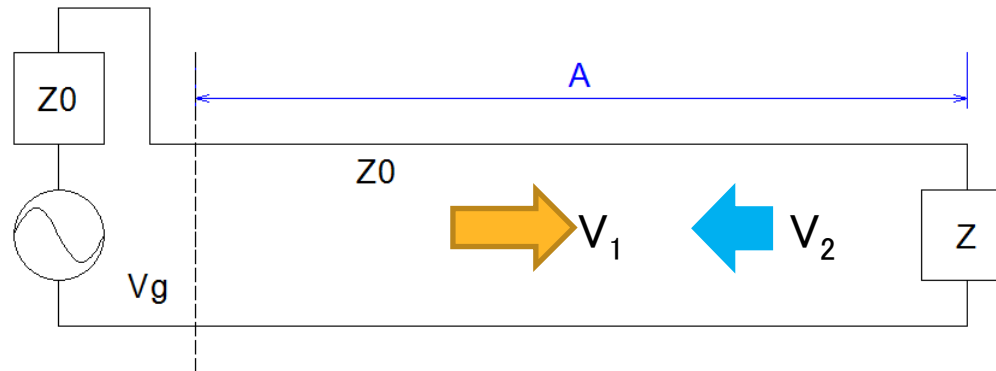
Impedance matched line



$$\frac{V(A)}{I(A)} = Z_0 = Z_0 \frac{V_1 e^{-j\beta A} + V_2 e^{j\beta A}}{V_1 e^{-j\beta A} - V_2 e^{j\beta A}} \quad V_2 = 0$$

- No reflection! (Only forwarding wave exist)

Arbitrary termination

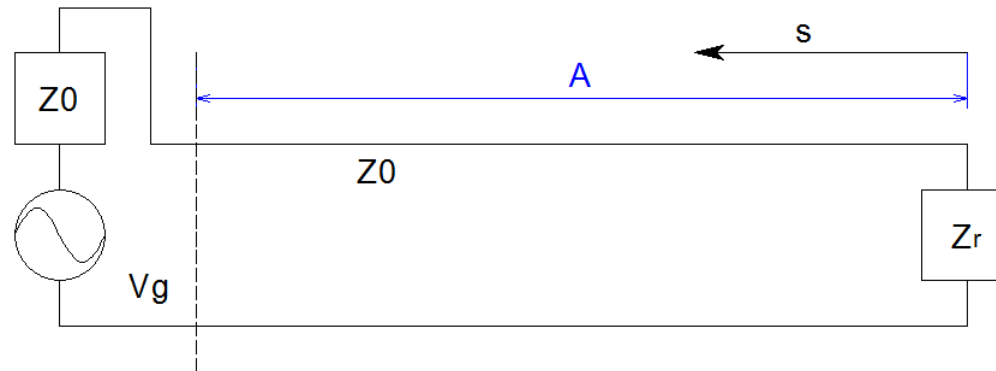


- To satisfy $V(A)/I(A)=Z$, we need both forwarding and reflecting wave.

$$V = V_1 e^{-j\beta z} \left(1 + 2 \frac{|V_2|}{|V_1|} \cos \chi + \frac{|V_2|^2}{|V_1|^2} \right)^{\frac{1}{2}} \exp \left(j \tan^{-1} \frac{\frac{|V_2|}{|V_1|} \sin \chi}{1 + \frac{|V_2|}{|V_1|} \cos \chi} \right)$$

$$\chi = 2\beta z + \theta_2 - \theta_1$$

Standing wave



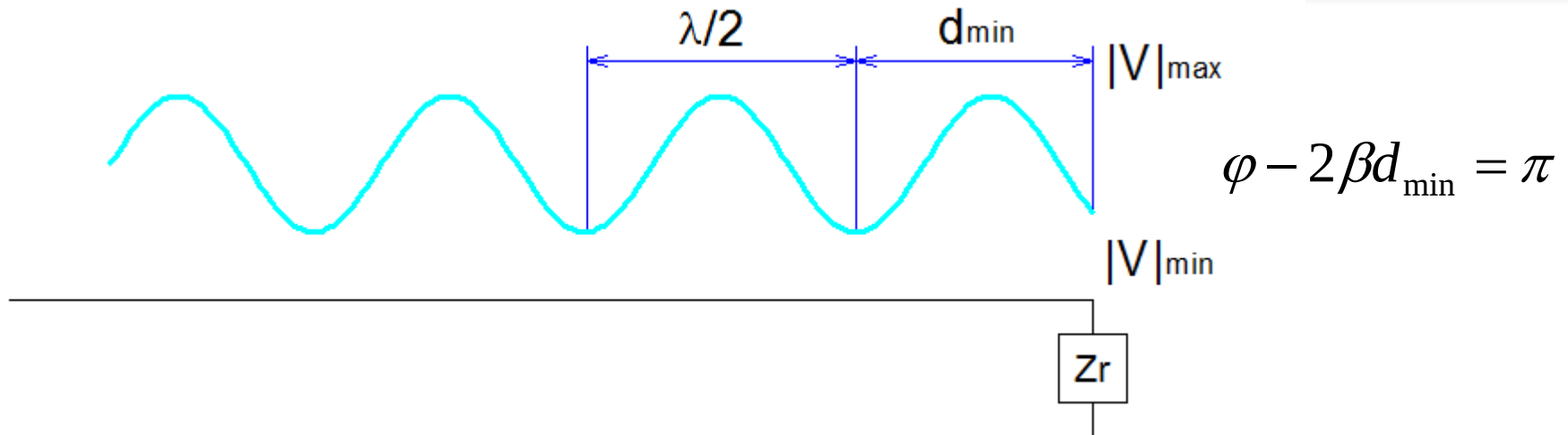
$$\begin{aligned}
 V &= V_1 e^{-j\beta(A-s)} + V_2 e^{j\beta(A-s)} = V_1' e^{j\beta s} + V_2' e^{-j\beta s} \\
 &= V_1' e^{j\beta s} (1 + \rho e^{-2j\beta s})
 \end{aligned}$$

- ρ : reflection constant

$$\rho = \frac{V_2'}{V_1'} = |\rho| e^{j\varphi}$$

$$V = V_1' e^{j\beta s} (1 + |\rho| e^{j(\varphi - 2\beta s)})$$

Standing wave ratio

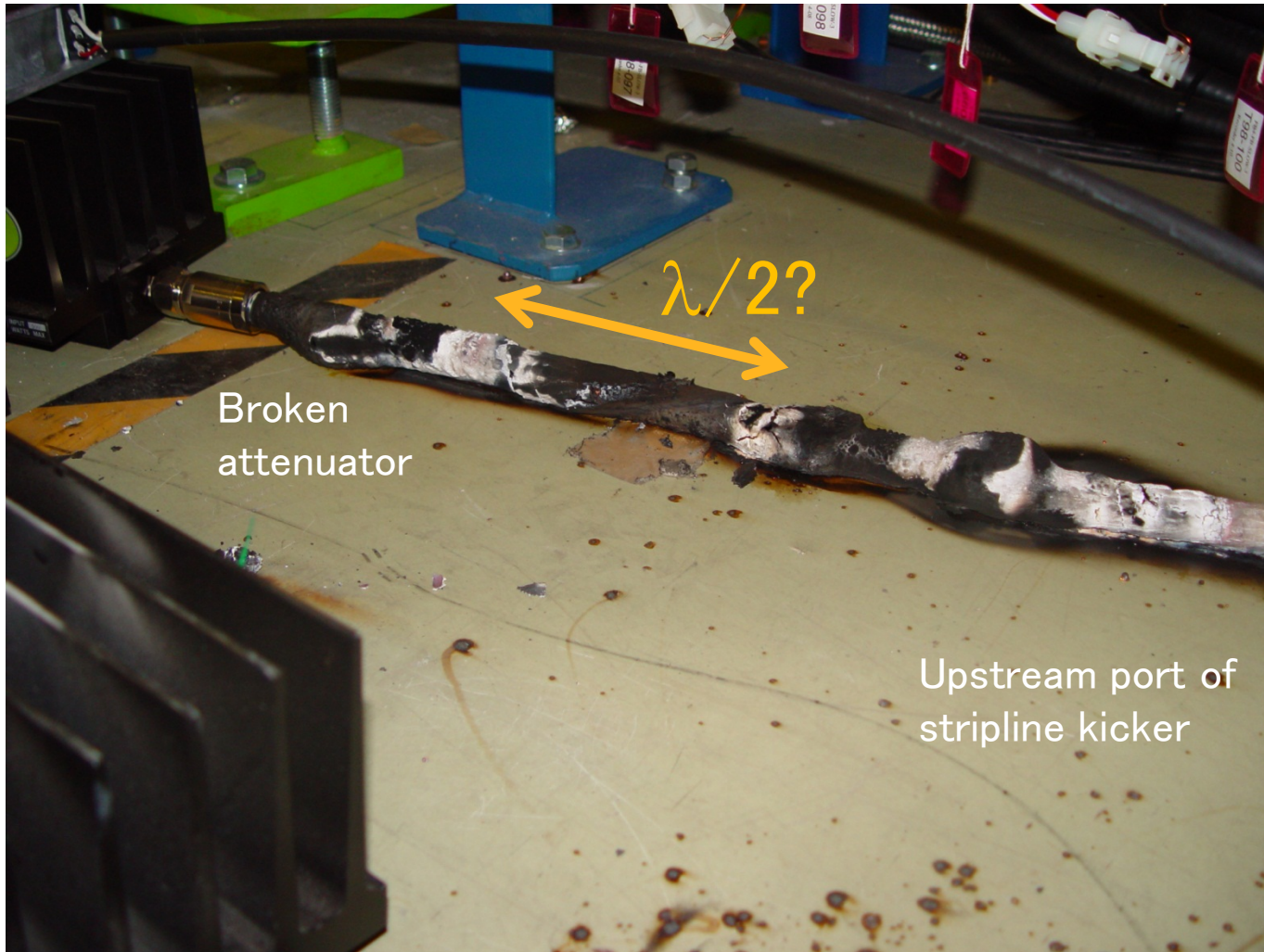


■ Standing wave ratio (SWR)

$$S = \frac{|V|_{\max}}{|V|_{\min}} = \frac{1 + |\rho|}{1 - |\rho|}$$

$$|\rho| = \frac{S - 1}{S + 1}$$

Example of standing wave!

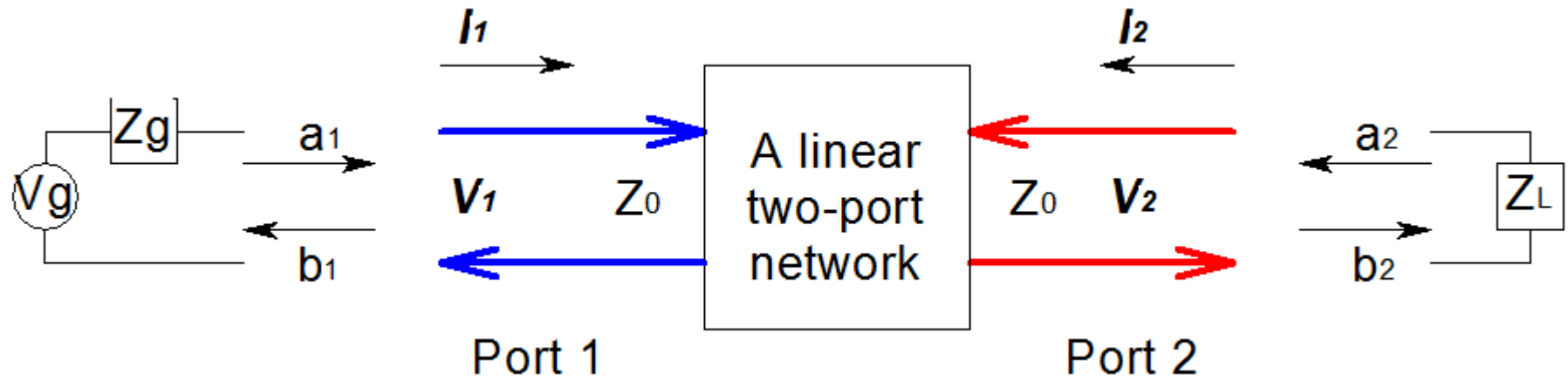


Impedance of the load

- We can estimate the load impedance using

$$\begin{aligned}
 Z_r &= Z_0 \frac{1 + \rho}{1 - \rho} \quad \begin{array}{l} \text{Reflection} \\ \text{constant} \end{array} \\
 \frac{Z_r}{Z_0} &= \frac{1 + |\rho| e^{j\varphi}}{1 - |\rho| e^{j\varphi}} = \frac{(S + 1) + (S - 1)e^{j(2\beta d_{\min} + \pi)}}{(S + 1) - (S - 1)e^{j(2\beta d_{\min} + \pi)}} \quad \text{SWR} \\
 &= \frac{1 - jS \tan \beta d_{\min}}{S - j \tan \beta d_{\min}}
 \end{aligned}$$

Linear two port network



$$\begin{pmatrix} \mathbf{b}_1 \\ \mathbf{b}_2 \end{pmatrix} = \begin{pmatrix} S_{11} & S_{12} \\ S_{21} & S_{22} \end{pmatrix} \begin{pmatrix} \mathbf{a}_1 \\ \mathbf{a}_2 \end{pmatrix}$$

S-parameters

- Input Reflection Coefficient with $Z_L=Z_0$

$$S_{11} = \left. \frac{b_1}{a_1} \right|_{a_2=0}$$

Input match

- Output Reflection Coefficient with $Z_G=Z_0$ and $V_G=0$

$$S_{22} = \left. \frac{b_2}{a_2} \right|_{a_1=0}$$

Output match

- Forward Transmission Coefficient with $Z_L=Z_0$

$$S_{21} = \left. \frac{b_2}{a_1} \right|_{a_2=0}$$

Gain or loss

- Reverse Transmission Coefficient with $Z_G=Z_0$ and $V_G=0$

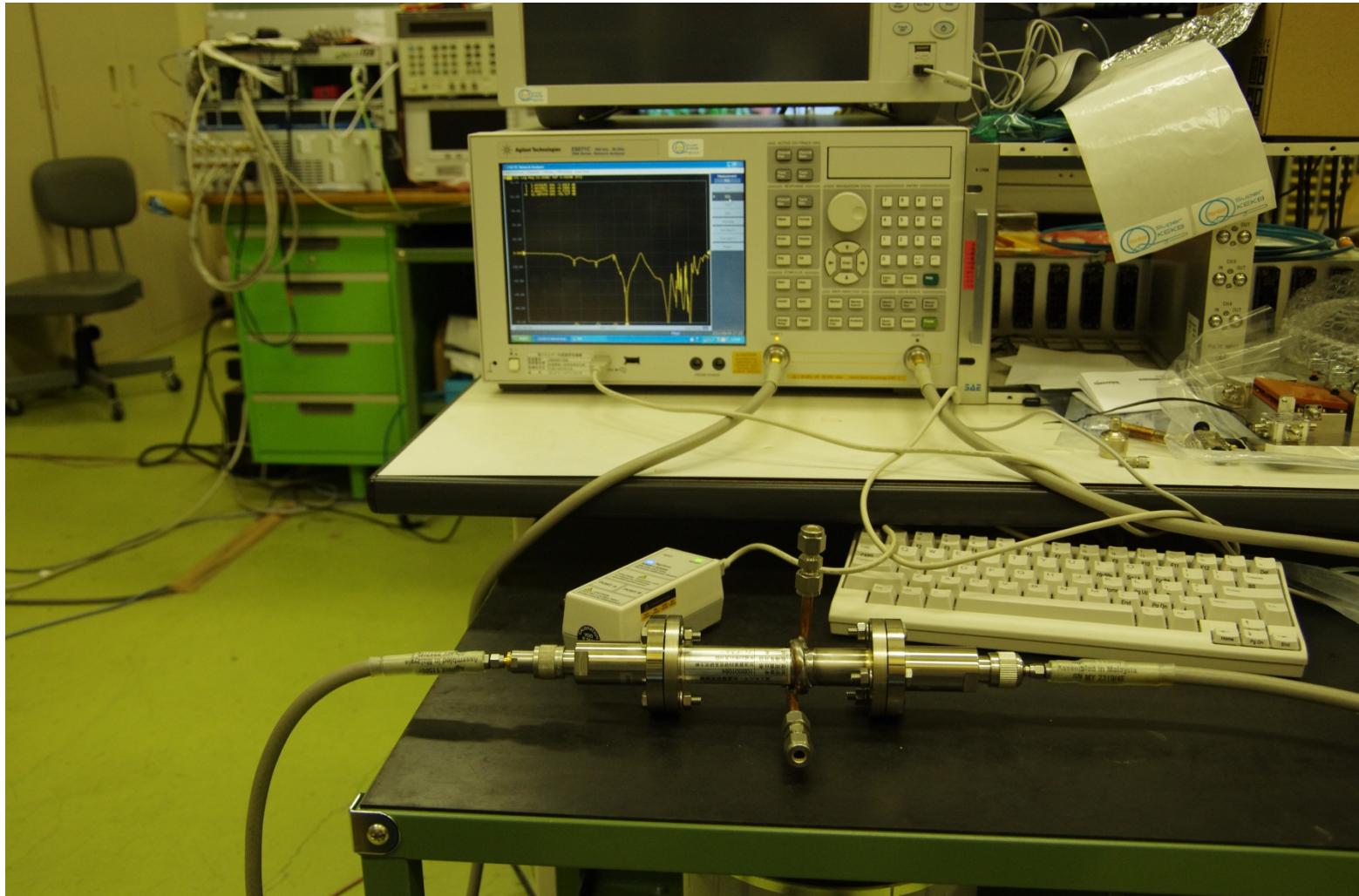
$$S_{12} = \left. \frac{b_1}{a_1} \right|_{a_2=0}$$

Isolation

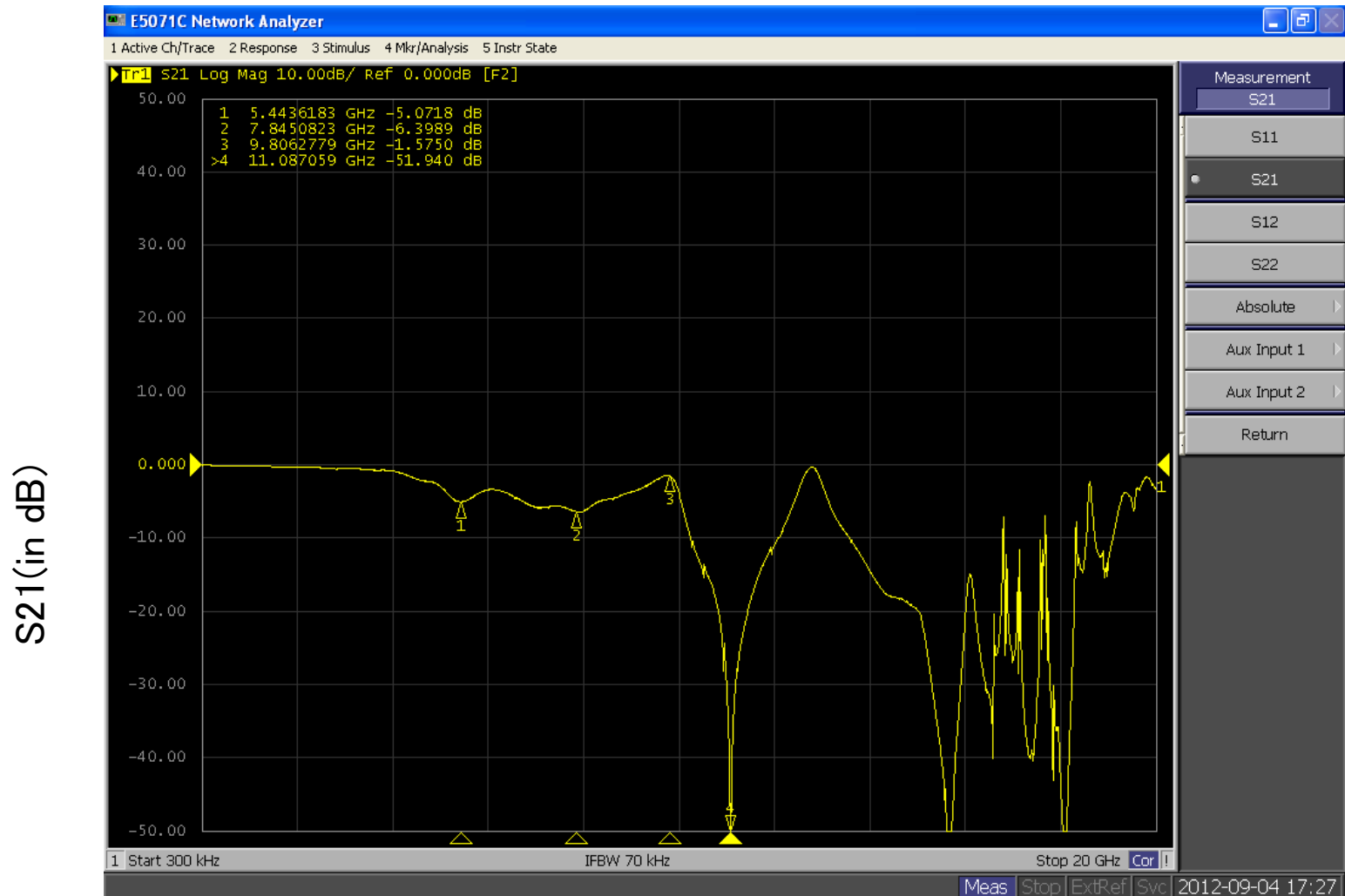
Why Use S-Parameters?

- **relatively easy to obtain at high frequencies**
 - measure voltage traveling waves with a vector network analyzer
 - don't need shorts/opens which can cause active devices to oscillate or self-destruct
- **relate to familiar measurements (gain, loss, reflection coefficients...)**
- **can cascade S-parameters of multiple devices to predict system performance**
- **can compute H, Y or Z parameters from S-parameters if desired**
- **can easily import and use S-parameter files in electronic-simulation tools**

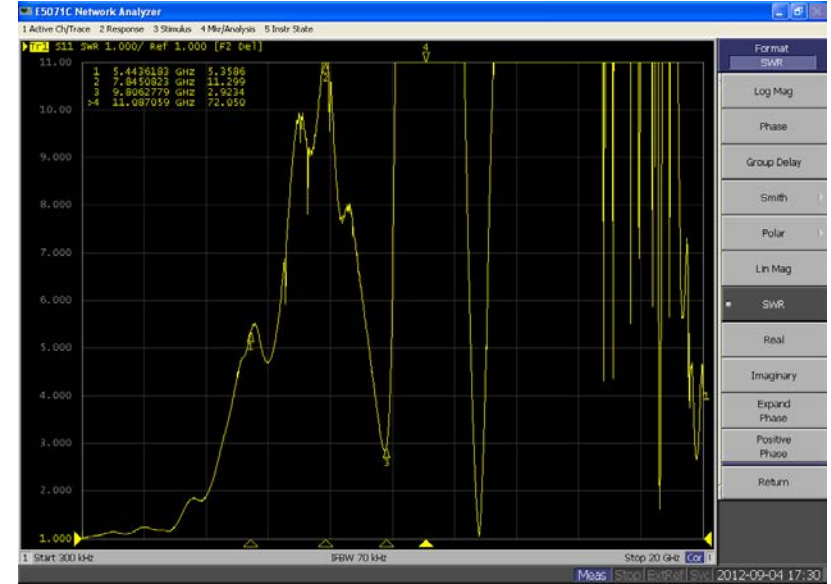
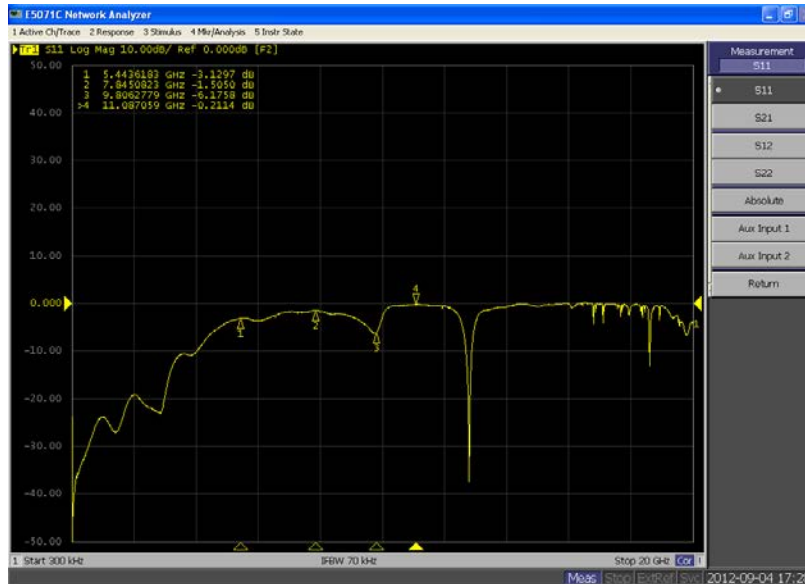
RF Network Analyzer



S21



S11 and SWR(VSWR)

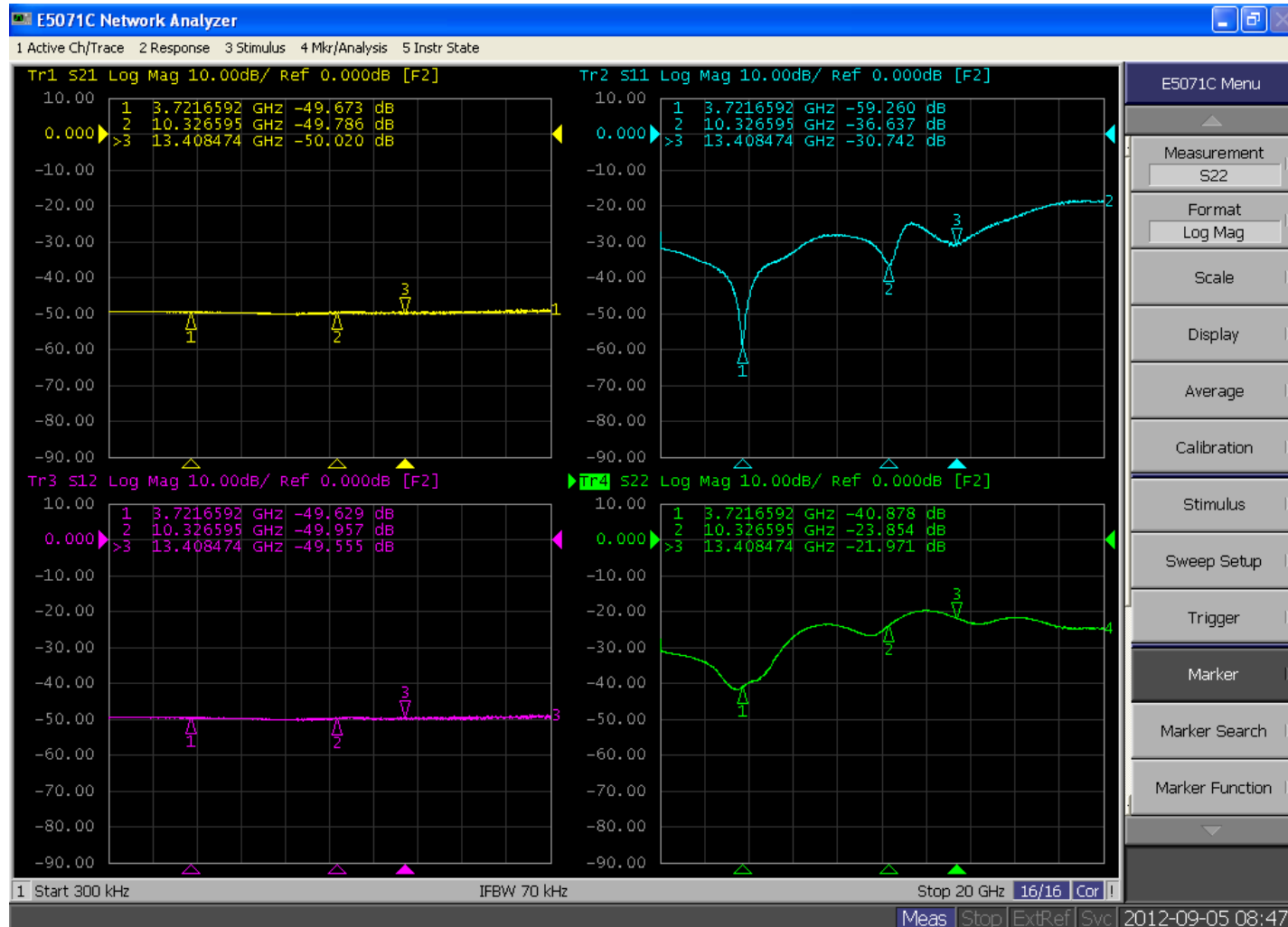


- Return loss

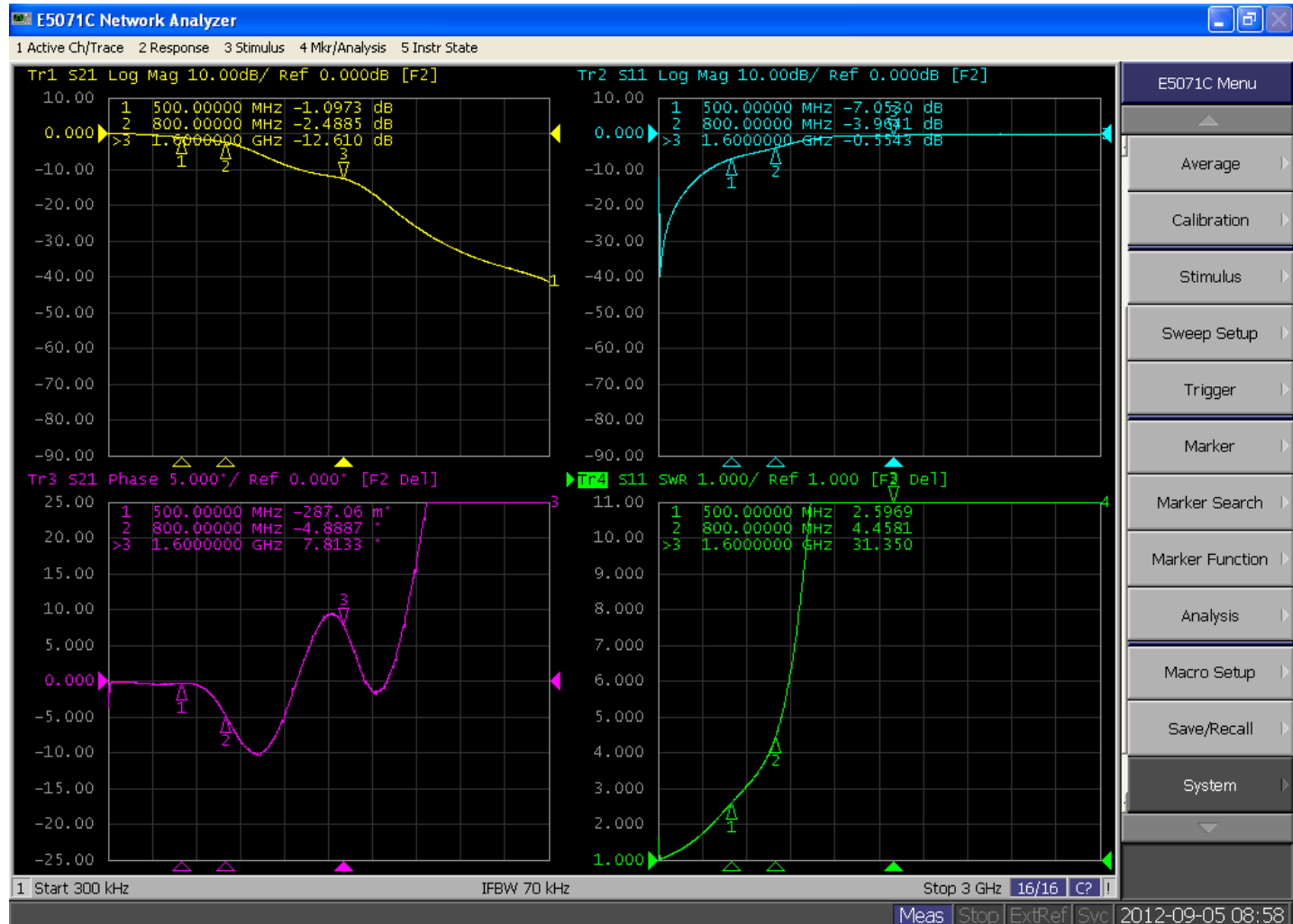
$$20 \log_{10} |S_{11}| \text{ dB}$$

$$SWR_{input} = \frac{1 + |S_{11}|}{1 - |S_{11}|}$$

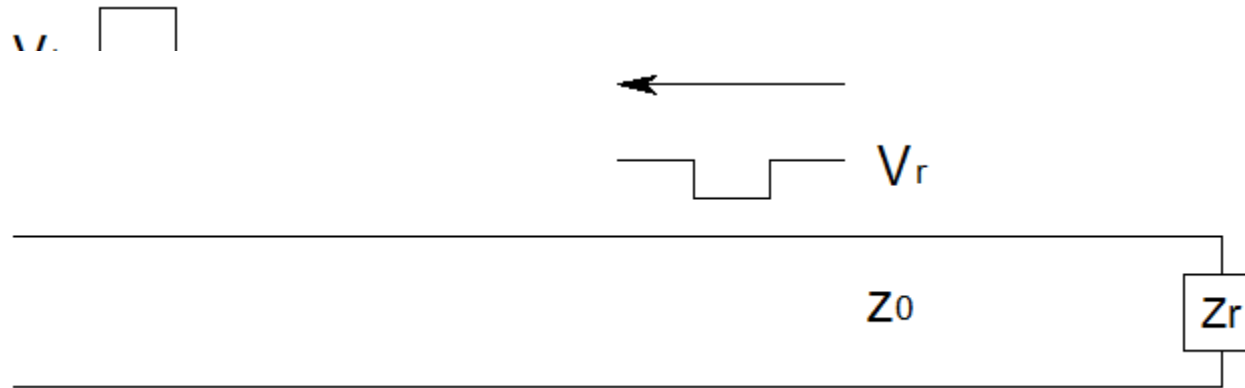
Example (50dB attenuator)



Example (800MHz Bessel LPF)



Time domain behavior--TDR



- Using voltage ratio between forward and reflecting wave

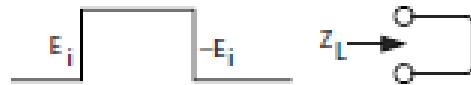
$$Z_r = \frac{1 + \rho}{1 - \rho} Z_0$$

$$\rho = \frac{V_r}{V_i}$$

(A) Open Circuit Termination ($Z_L = \infty$)

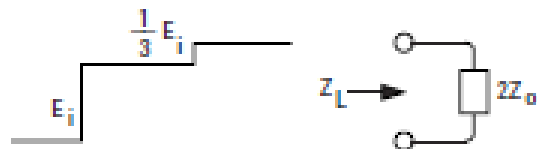
$$(A) E_r = E_i$$

Therefore $\frac{Z_L - Z_0}{Z_L + Z_0} = +1$
 Which is true as $Z_L \rightarrow \infty$
 $\therefore Z = \text{Open Circuit}$

(B) Short Circuit Termination ($Z_L = 0$)

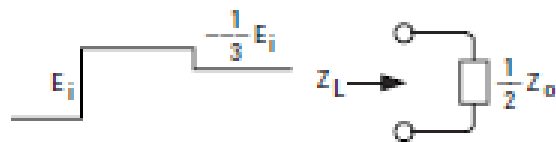
$$(B) E_r = -E_i$$

Therefore $\frac{Z_L - Z_0}{Z_L + Z_0} = -1$
 Which is only true for finite Z
 When $Z_L = 0$
 $\therefore Z = \text{Short Circuit}$

(C) Line Terminated in $Z_L = 2Z_0$

$$(C) E_r = +\frac{1}{3} E_i$$

Therefore $\frac{Z_L - Z_0}{Z_L + Z_0} = +\frac{1}{3}$
 and $Z_L = 2Z_0$

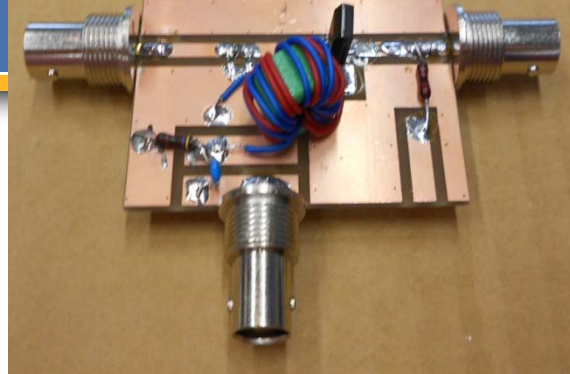
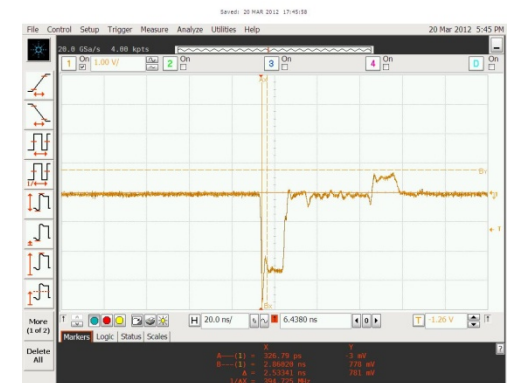
(D) Line Terminated in $Z_L = \frac{1}{2} Z_0$

$$(D) E_r = -\frac{1}{3} E_i$$

Therefore $\frac{Z_L - Z_0}{Z_L + Z_0} = -\frac{1}{3}$
 and $Z_L = \frac{1}{2} Z_0$

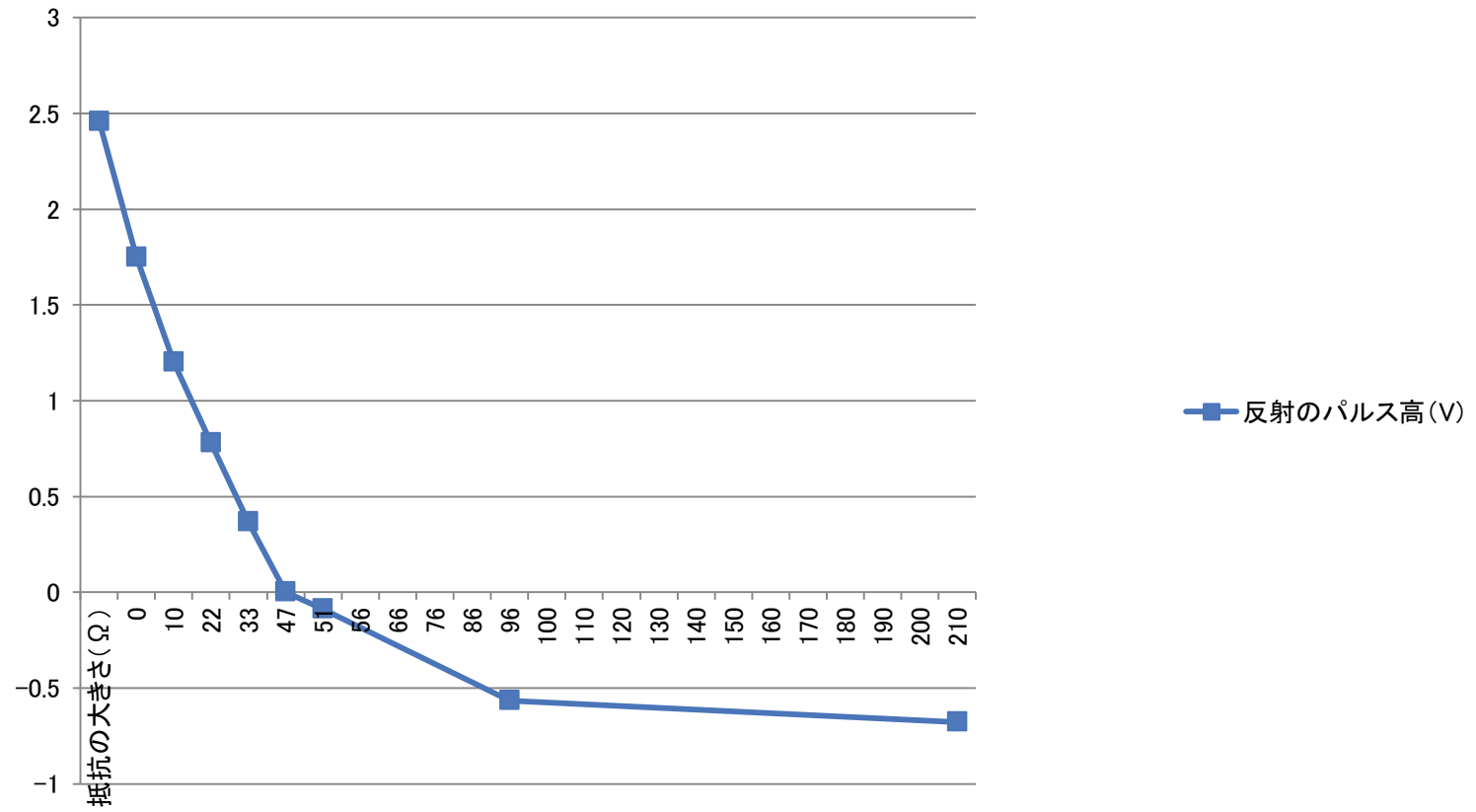
Science Camp 2011 (for High School students)



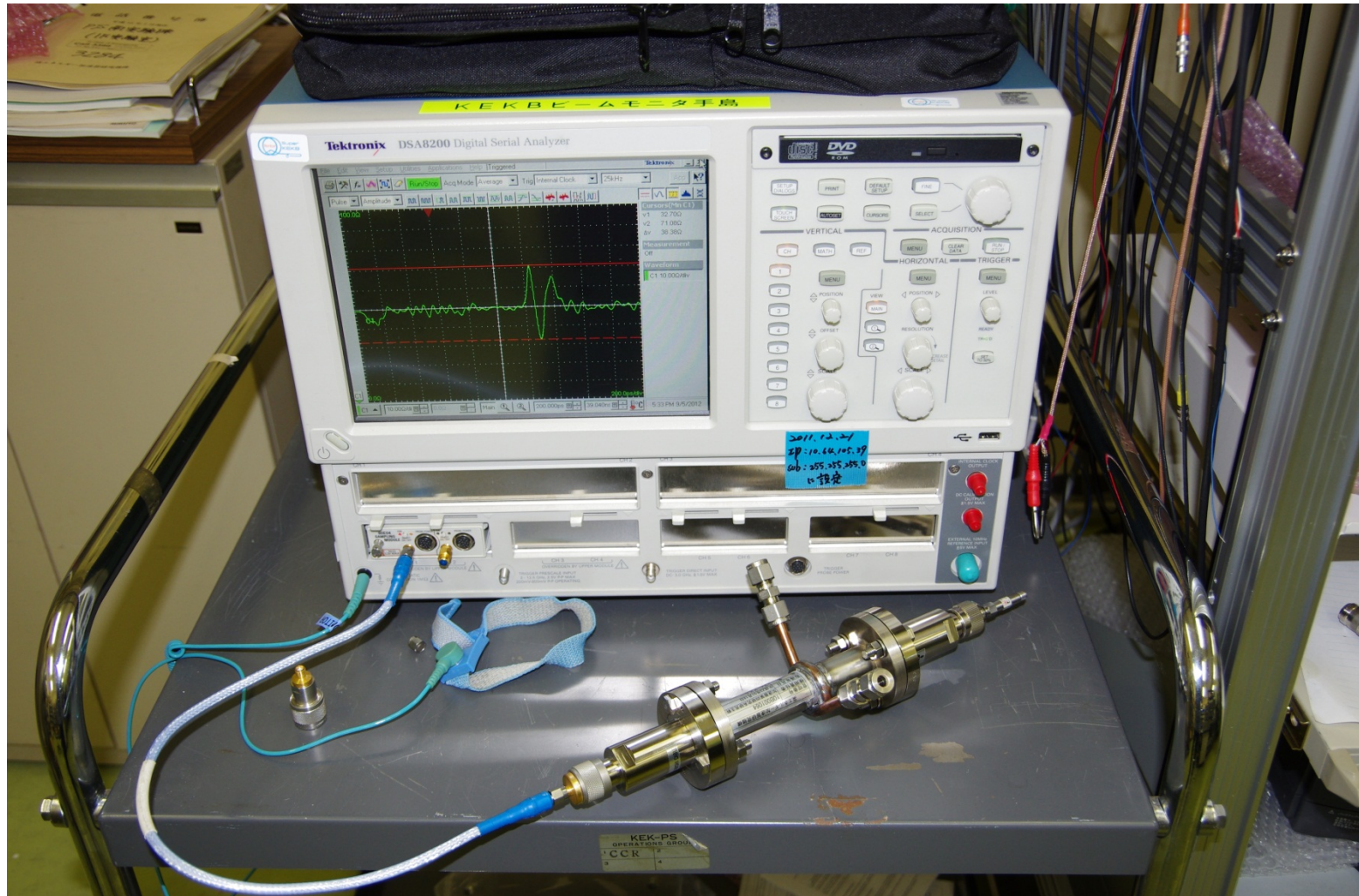
51 Ω 470 Ω 33 Ω

Matching of 50-ohm line

Reflection (V)



Real TDR



Tips

- **Good matched two-ports (such as J-J structure) is needed to measure the S-parameters of the feedthrough structure.**
 - For the TDR measurements, open structure (button or rod on vacuum side) might usually be OK



Ideal feedthrough?

- **Mechanical**

- Completely satisfy required mechanical toughness
- Satisfy vacuum requirements

- **Frequency domain**

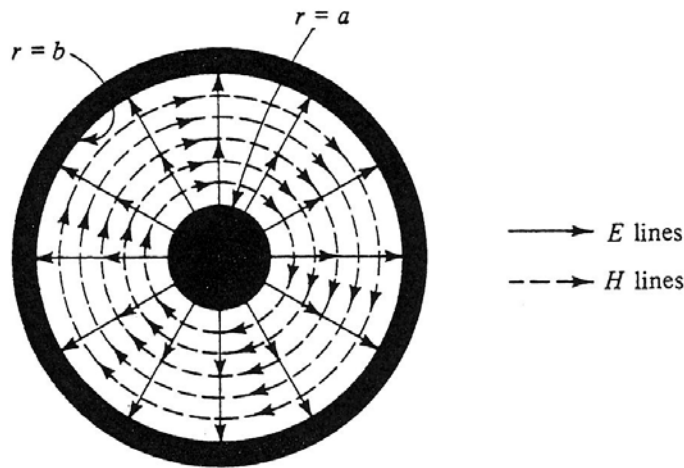
- S_{21} (and S_{12}) ~ 1 (0dB)
- S_{11} (and S_{22}) $\sim -\infty$ dB

- **Time domain**

- Impedance=50 Ohm, completely matched structure

Size of the feedthrough

- Which connectors do you want to use?
 - N?, SMA?, BNC?, 7/16-DIN?, 7/8-EIA?



$$Z_0 = 60 \sqrt{\frac{\mu_R}{\epsilon_R}} \ln \frac{b}{a}$$

Attenuation Length

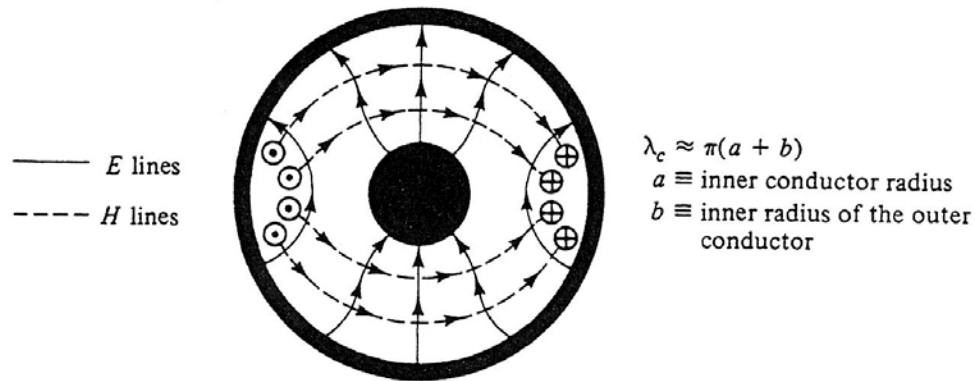
$$\alpha \approx \alpha_c + \alpha_d$$

$$\alpha_c = 13.6 \frac{\delta_s \sqrt{\epsilon_R} \{1 + (b/a)\}}{\lambda_0 b \ln(b/a)},$$

$$\alpha_d = 27.3 \frac{\sqrt{\epsilon_R}}{\lambda_0} \tan \delta$$

Higher-mode propagation in coaxial lines.

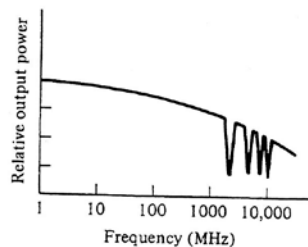
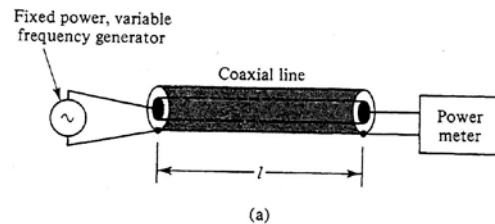
■ TE₁₁mode



$$\lambda_c \approx \pi(a + b)$$

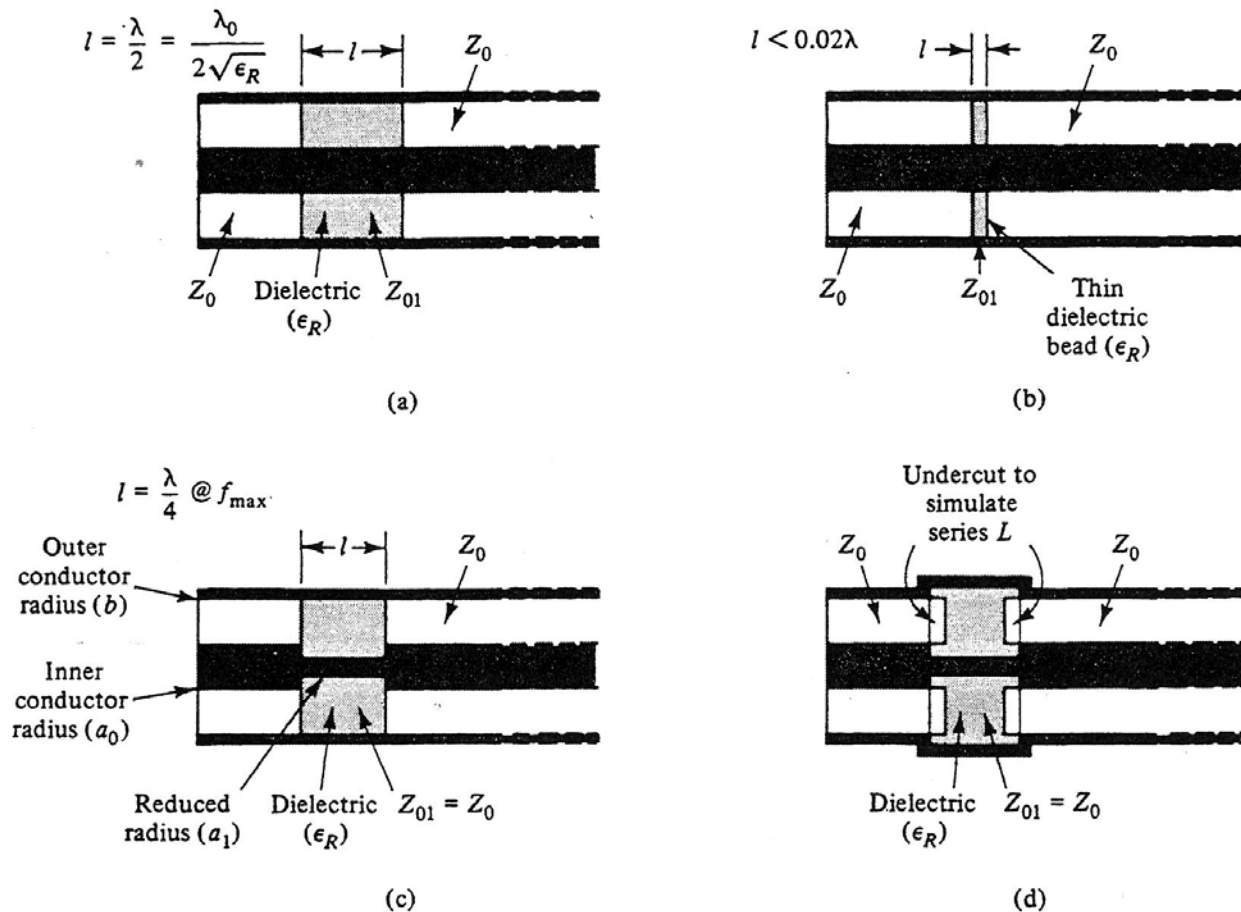
$$f_c \approx \frac{c}{\pi(a + b)\sqrt{\epsilon_R}}$$

Figure 5-3 The electromagnetic field pattern for the TE_{11} mode in a coaxial line.



- Type-N: 18GHz
- SMA: 34GHz
- RG-223: ~30GHz
- EIA 7/8": ~6.8GHz

Connectors in the air



$$Z_{01} = \frac{Z_0}{\sqrt{\epsilon_R}}$$

Figure 6-8 Four types of dielectric bead supports for coaxial lines.

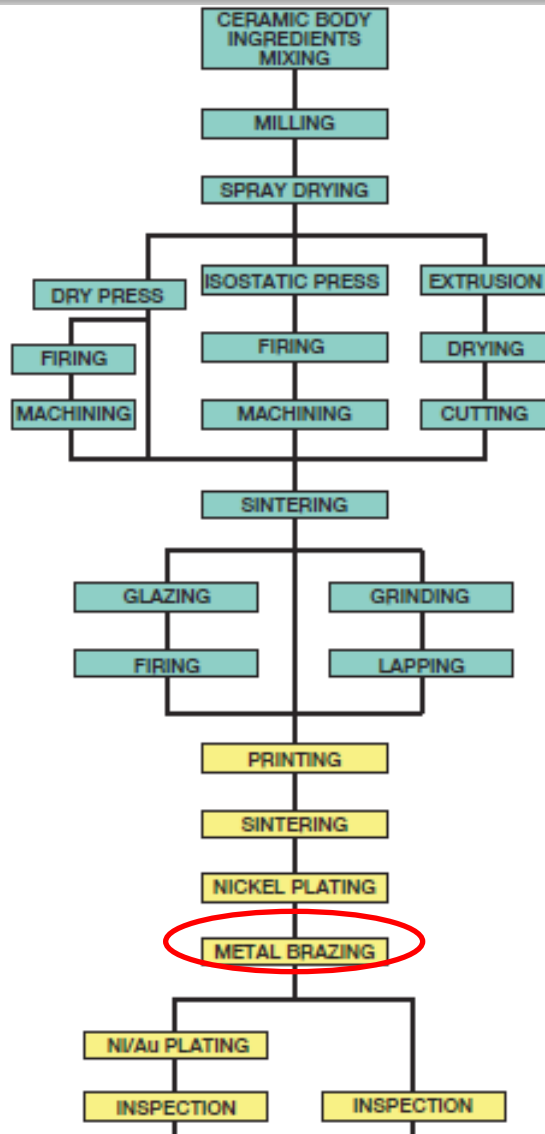
Feedthrough for vacuum

- **Vacuum seal (and support for inner conductor)**
 - Alumina ceramic ($\epsilon_R \sim 10$), Si_3N_4 (~ 8)
 - Glass ($\epsilon_R \sim 4-5$)
 - Much larger than the support used in the air (~ 2)
- **Need to stand mechanical stress coming from**
 - Vacuum pressure
 - (huge) pressure when connecting the cable (or attenuator) to the feedthrough
 - Thermal stress
 - Baking
 - Heating by the beam power
- **Need to keep good RF contact under severe condition**
 - Heat cycle
 - Radiation, active gas

Outer/inner conductor

- **Kovar (Nickel–cobalt ferrous alloy)**
 - Designed to be compatible with the thermal expansion characteristics of borosilicate glass
 - Ferromagnetics: Not so good for use near strong magnet.
 - Thermal conductivity : Low
- **Ti**
 - Non–magnetic material
- **Cu, Al, Stainless steel..**
 - Also be usable. Consult your ceramic company.

Feedthrough process



Brazing temperature

- ~800 degC
- After brazing process, metal parts will be well annealed – original characteristics might be changed.
 - No spring action at all!

Braze to vacuum chamber OK?

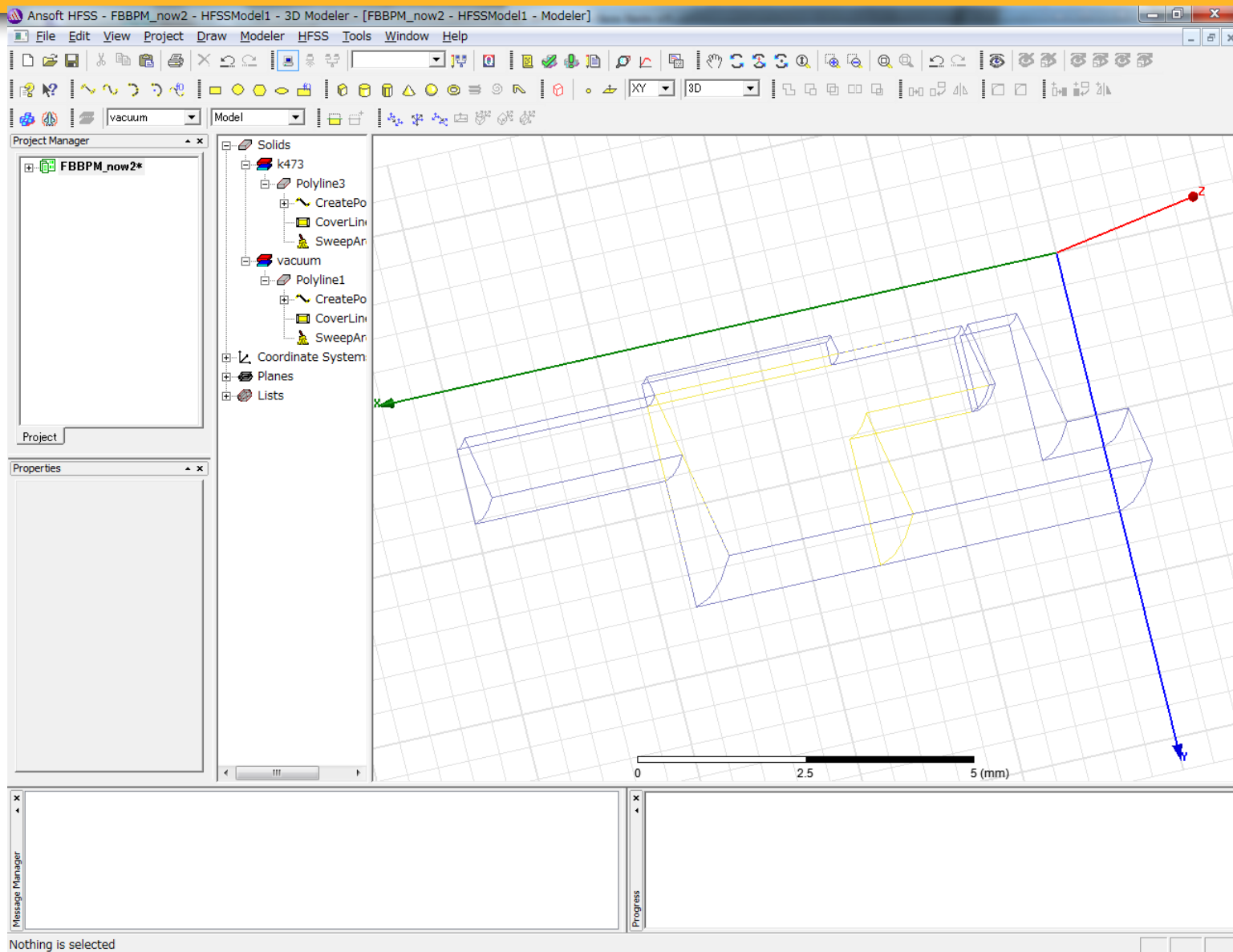
- Second (third?) brazing process
- There exist brazing materials with lower temperature
 - Not so easy to control the temperature

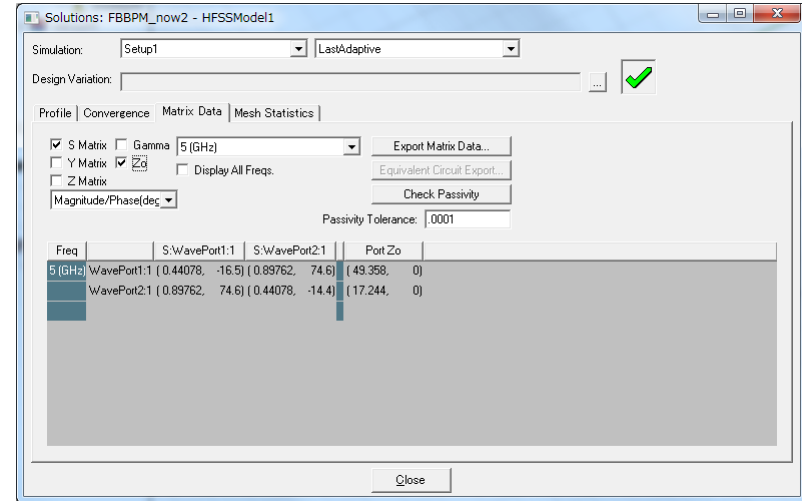
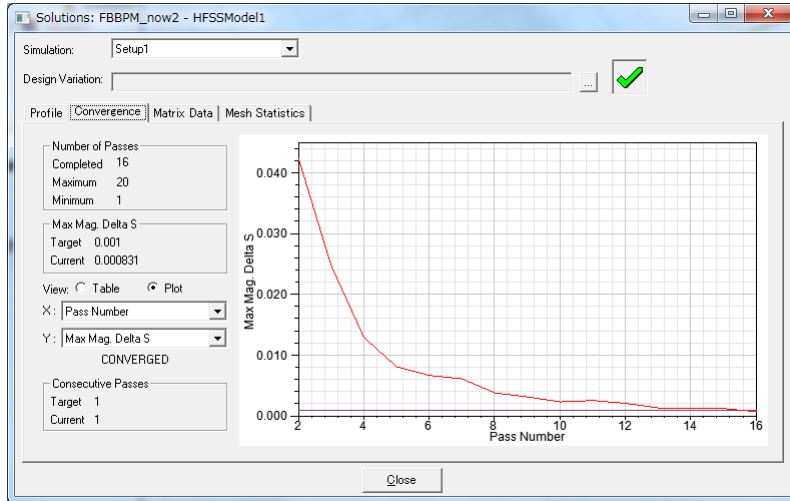
Frequency domain design

■ ANSYS (Ansoft) HFSS

- 3D full-wave electromagnetic field simulator
- Multiple state-of-the-art solver (finite element method or integral equation method)
- calculate S-parameters, field patterns, eigen values, impedances..
- Good user interface, Good interface to other tools such as ANSYS, etc.
- Automatic mesh handling
- (Very) Fast simulation speed

Example





Solutions: FBBPM_now2 - HFSSModel1

Simulation: Setup1

Design Variation:

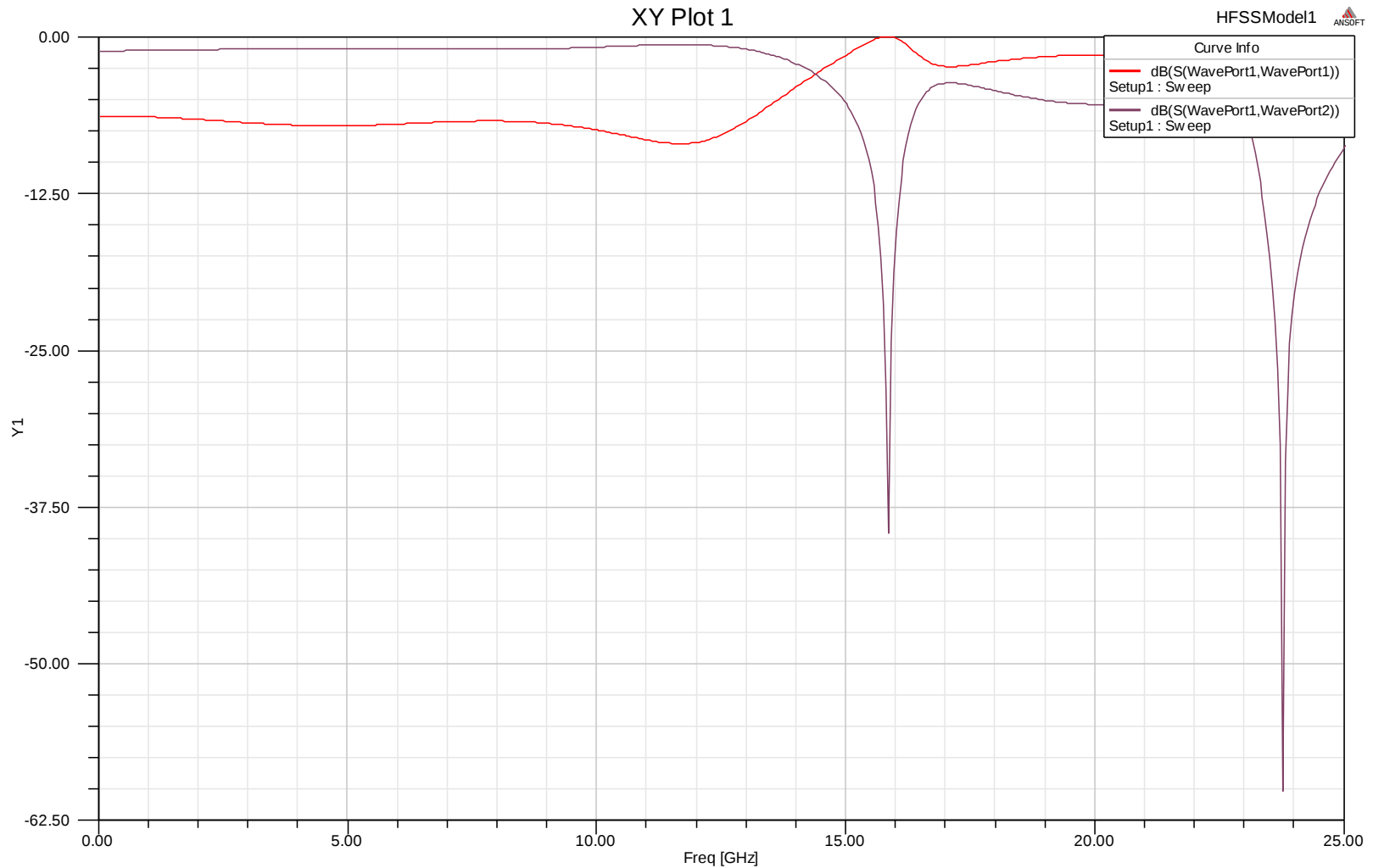
Profile | Convergence | Matrix Data | Mesh Statistics

Task	Real Time	CPU Time	Memory	Information
Frequency: 21.25 GHz				Full Solution # 19
Simulation Setup	00:00:00	00:00:00	35.4 M	Disk = 0 KBytes
Matrix Assembly	00:00:00	00:00:00	61 M	Disk = 0 KBytes, 9601 tetrahedra, WavePort1: 84 triangles, WavePort2: 90 tri
Solver MRS4	00:00:01	00:00:02	130 M	Disk = 0 KBytes, matrix size 61092, matrix bandwidth 20.7
Field Recovery	00:00:00	00:00:00	130 M	Disk = 0 KBytes, 2 excitations
				Interpolation Error: S Matrix error 0 %
				Interpolating sweep converged
Solution Process				Elapsed time : 00:00:39, Hfss ConEngine Memory : 46.7 M
Total	00:00:21	00:00:40		Time: 09/10/2012 11:16:56, Status: Normal Completion

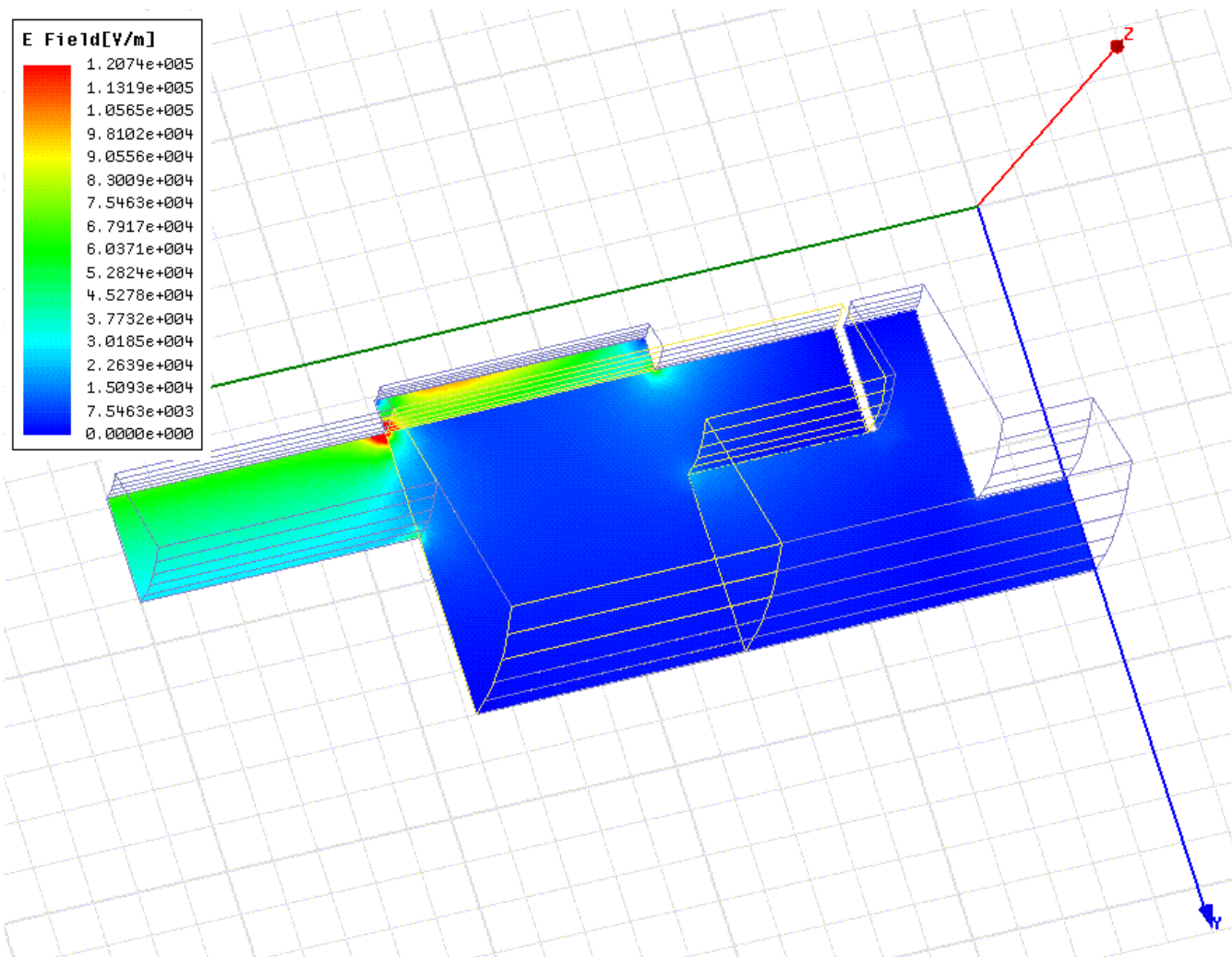
Export...

Close

(Fast) Frequency sweep



E-Field pattern



Time domain simulation

- **GdfidL Electromagnetic Field simulator**
 - Time dependent Fields in loss-free or lossy structure
 - Fields may be excited by port mode or relativistic line charge
 - Resonant fields in loss-free or lossy structure
- **Calculated result**
 - S-parameters, including power (voltage) value
 - Wake potentials including loss factor, impedance etc.
 - Q values and Shunt impedance
- **Need (some)large-scale parallel computing resources**
 - KEKB: 256 cores, 512GB Linux cluster
 - Text-base user interface, longer simulation time

Example of GdfidL input(1)

```

define(EL,1) define(MAG,2)
define(INF, 1000)

define(PipeRadius, 25.40e-3/2)
define(PipeStart, 100.0e-3)
define(PipeEnd,100.0e-3)
define(BpmAdd,13.5e-3)
define(STPSIZE,0.1e-3)

-general
  outfile= /users/tobiyama/GD/bpm-CL22/temp/
  scratchbase =/users/tobiyama/GD/scratch/
-material
  material=10
  type=electric
  material=15
  type=normal, epsr=9.7, muer=1, kappa=0, mkappa=0

```

```

-mesh
  spacing=0.1e-3
  pxlow= 0
  pxhigh=(PipeRadius+BpmAdd-5*STPSIZE)
  pylow= 0
  pyhigh=(PipeRadius+BpmAdd-5*STPSIZE)
  pzlow=-PipeStart+5*STPSIZE
  pzhigh=PipeEnd-5*STPSIZE

  cxlow=magnetic, cxhigh=electric
  cylow=magnetic, cyhigh=electric
  czlow=electric, czhigh=electric

-brick
  material=EL
  xlow= -INF, xhigh=INF
  ylow= -INF, yhigh=INF
  zlow= -INF, zhigh=INF
  doit

```

Example of GdfidL input(2)

```
#
# cave beam pipe
#
-gbor
material=0
origin=(0,0,0)
zprimedirection= (0,0,1)
rprimedirection= (1,0,0)
range= (0,360)
```

```
clear
```

```
point(-PipeStart,0)
point(-PipeStart,PipeRadius)
point(PipeEnd,PipeRadius)
point(PipeEnd,0)
point(-PipeStart,0)
show=all
doit
```

```
#
# bpm block
#
macro BpmBlock
define(Dist, @arg1)
define(Angle, (@arg2)*@pi/180)

define(BpmDiskRadius, 6e-3/2)
define(BpmRodRadius, 1.8e-3/2)
define(BpmairRadius, 1.1e-3/2)
define(BpmOutRadius1, 8e-3/2)
define(BpmOutRadius2, 4.1e-3/2)
define(BpmCera1Radius, 4.1e-3/2)
define(BpmCera2Radius, 8e-3/2)
define(BpmDiskLength, 1e-3)
define(BpmRod1Length, 2.9e-3)
define(BpmRod2Length, 3e-3)
define(BpmRod3Length, 6.1e-3)

define(Cerastart, 1.9e-3)
define(Cera1Length, 2e-3)
define(Cera2Length, 3e-3)

define(DP1, (5e-
3+BpmDiskLength+BpmRod1Length+BpmRod2Length))
define(DP2, (DP1+Dist - 5e-3))
```

Example of GdfidL input(3)

```
#
-gccylinder
material=0, radius=BpmOutRadius1,length = DP1
origin=(cos(Angle)*(Dist - 5e-3), sin(Angle)*(Dist - 5e-3), 0)
direction=(cos(Angle),sin(Angle),0)
doit
-gccylinder
material=0, radius=BpmOutRadius2
length= BpmRod3Length
origin=(cos(Angle)*(DP2),sin(Angle)*(DP2), 0)
direction=(cos(Angle),sin(Angle),0)
doit
#
# ceramic
#
-gccylinder
material=15, radius=BpmCera1Radius,length=Cera1Length
origin=(cos(Angle)*(Dist+Cerastart), sin(Angle)*(Dist+Cerastart), 0)
direction=(cos(Angle),sin(Angle),0)
doit
-gccylinder
material=15, radius=BpmCera2Radius,length=Cera2Length
origin=(cos(Angle)*(Dist+Cerastart+Cera1Length),¥
      sin(Angle)*(Dist+Cerastart+Cera1Length), 0)
direction=(cos(Angle),sin(Angle),0)
doit
```

```
# air again
-gccylinder
material=0, radius=BpmRodRadius,length =
(Cera1Length+Cera2Length)
origin=(cos(Angle)*(Dist+Cerastart),sin(Angle)*(Dist-Cerastart) 0)
direction=(cos(Angle),sin(Angle),0)
doit
# bpm disk
-gccylinder
material=10, radius=BpmDiskRadius,length=BpmDiskLength
origin=(cos(Angle)*(Dist), sin(Angle)*(Dist), 0)
direction=(cos(Angle),sin(Angle),0)
doit
-gccylinder
material=10, radius=BpmRodRadius, length=BpmRod1Length
origin=(cos(Angle)*(Dist+BpmDiskLength),¥
      sin(Angle)*(Dist+BpmDiskLength), 0)
direction=(cos(Angle),sin(Angle),0)
doit

....still many definitions...

endmacro #BpmBlock
```

Example of GdfidL input(4)

```
call BpmBlock(13.2e-3,90)
call BpmBlock(13.2e-3,0)
call BpmBlock(13.2e-3,-90)
call BpmBlock(13.2e-3,180)
```

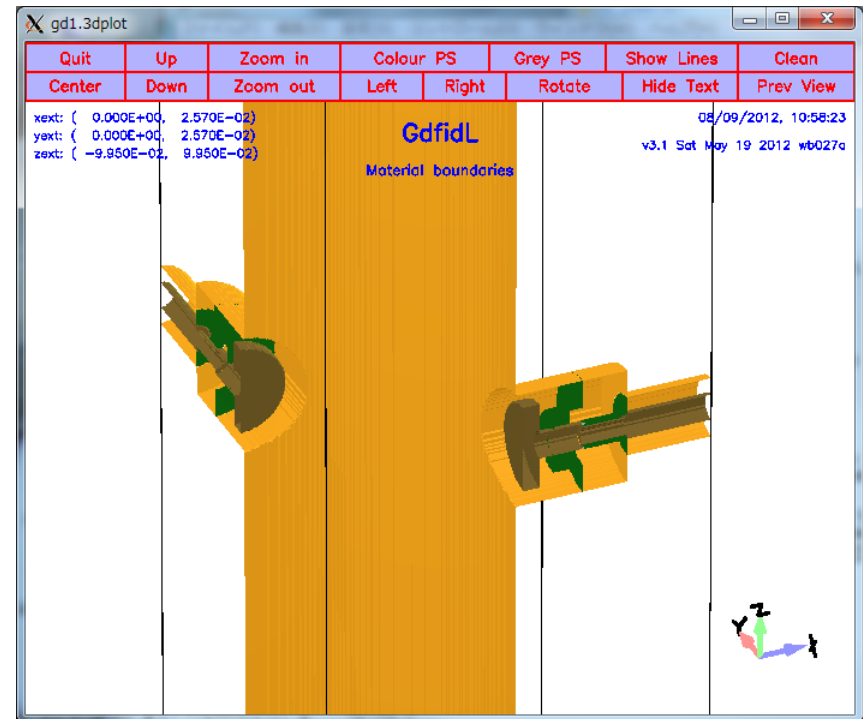
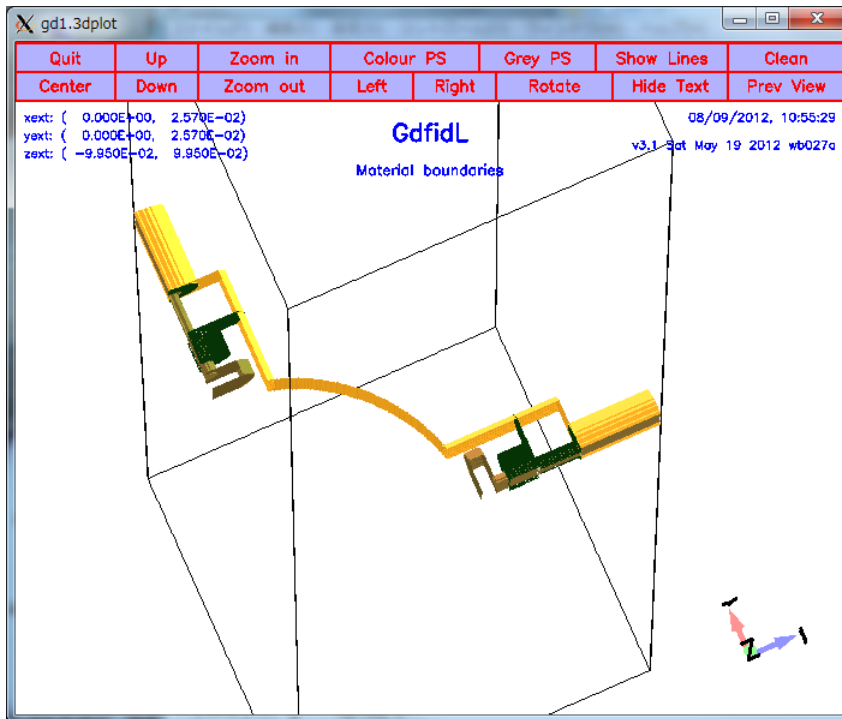
```
-fddd
-lcharge
  charge=1e-12
  sigma=6e-3
  xposition=0, yposition=0
  shigh=5
  showdata=no
```

```
-ports
  name=beamlow, plane=zlow, modes=0, npml=40, doit
  name=beamhigh, plane=zhigh, modes=0, npml=40, doit
  name=bpmyp, plane=yhigh, modes=1, npml=15, doit
  name=bpmxp, plane=xhigh, modes=1, npml=15, doit
```

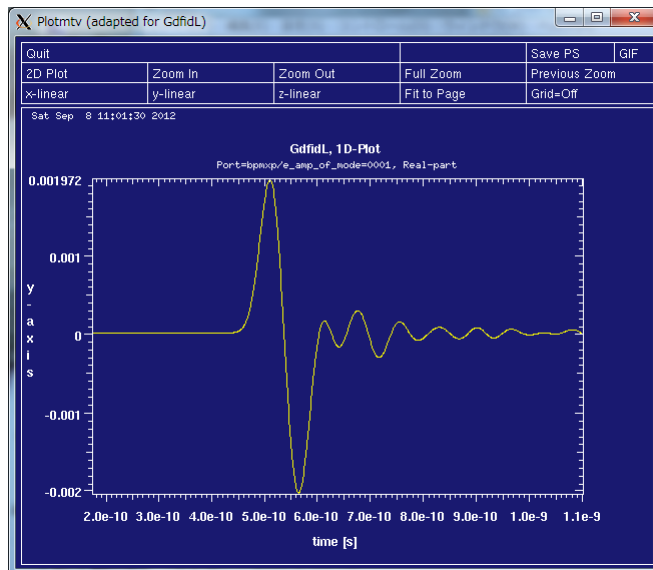
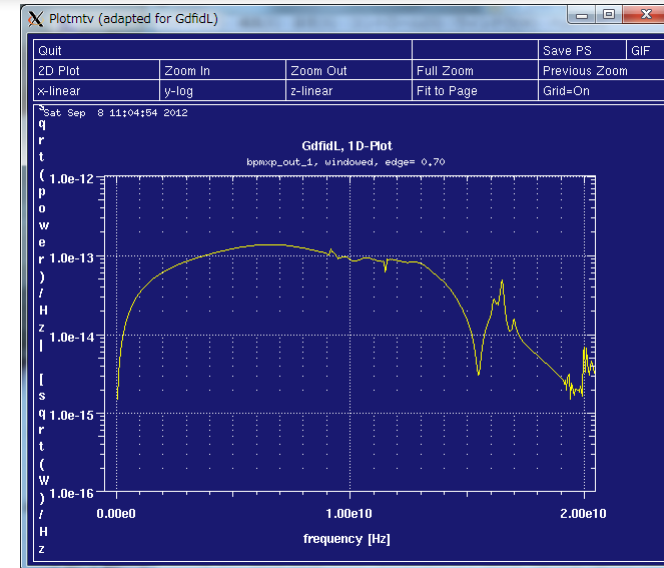
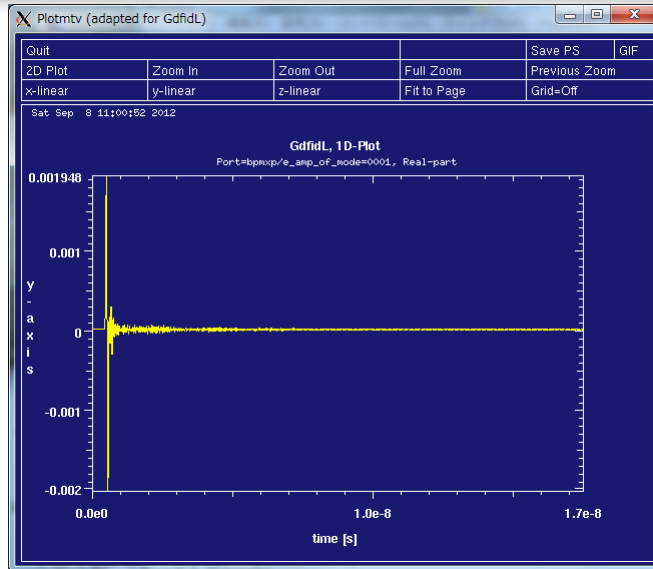
```
-fddd
doit
```

- **mesh 0.1mm**
- **bunch length 6mm**
- **beam=(0,0) [center]**
- **wake up to 5m**

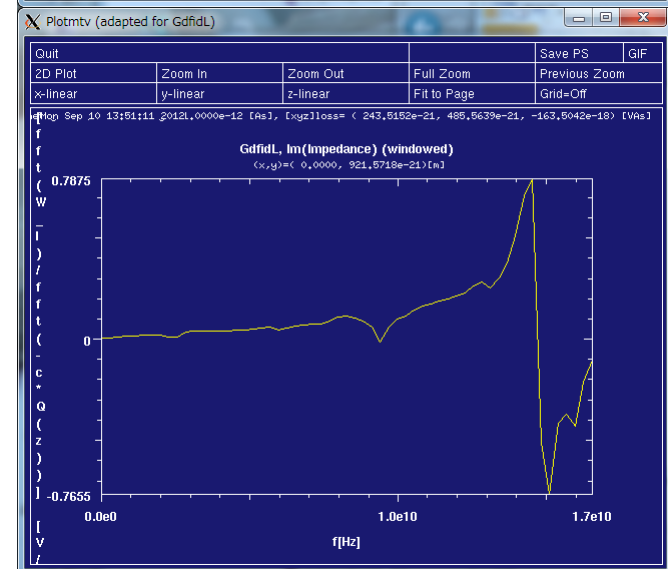
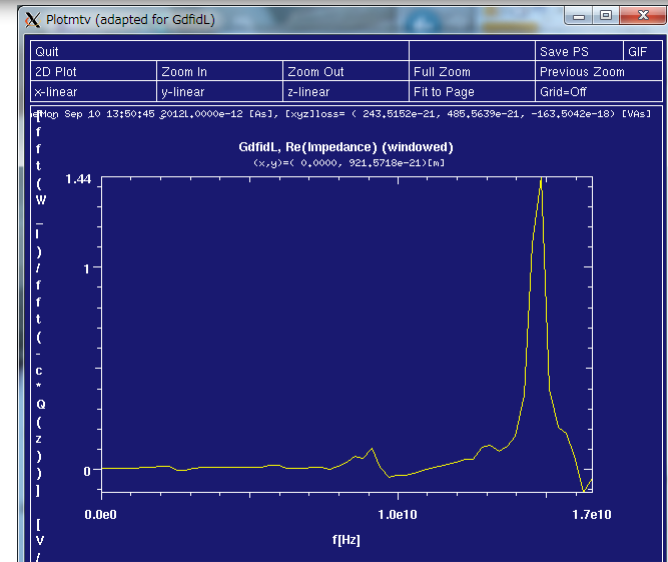
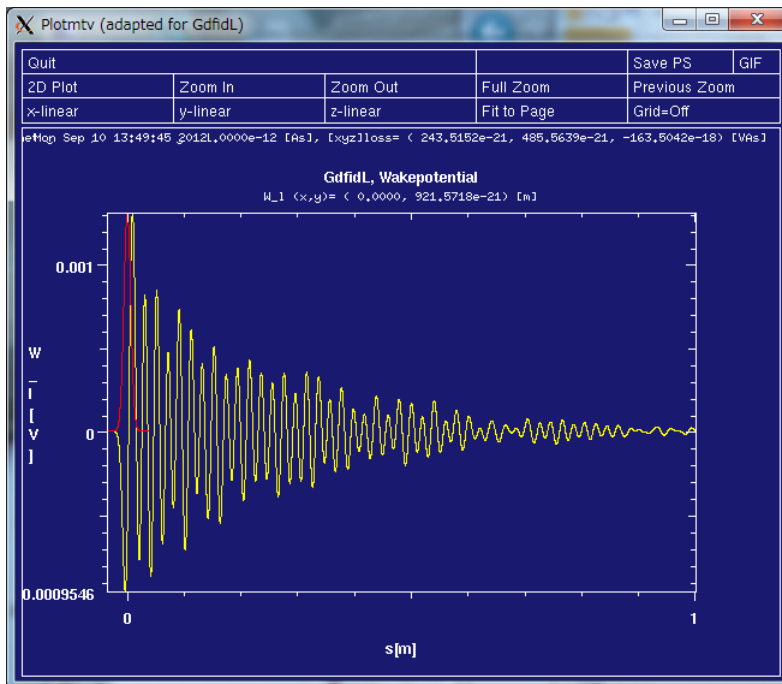
Model view



Post processing (using gd1.pp)

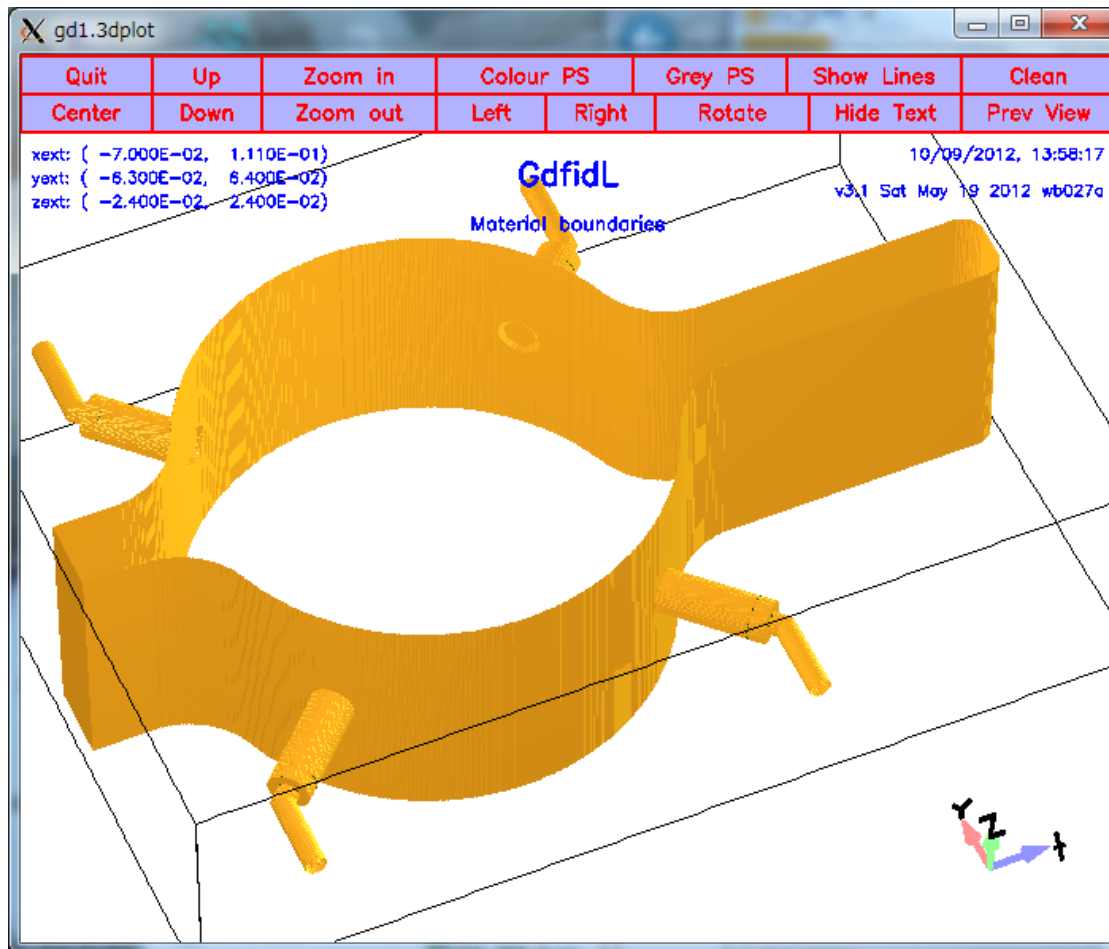


wakes, impedances

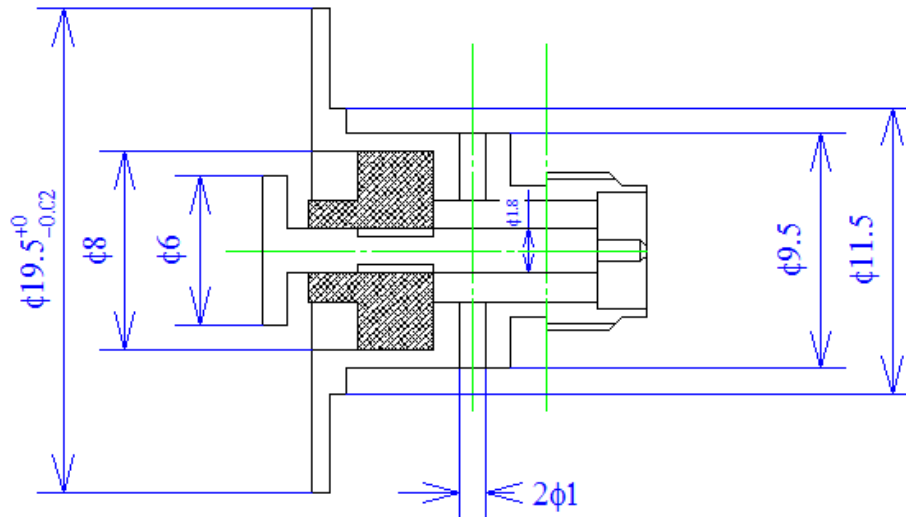


Tips

- Ports must be placed orthogonally to the boundaries.



Button electrode (KEKB-FB)



Feedback用SMAフィードスルーC型概略図

作図: 飛山真理 19/Mar/2004

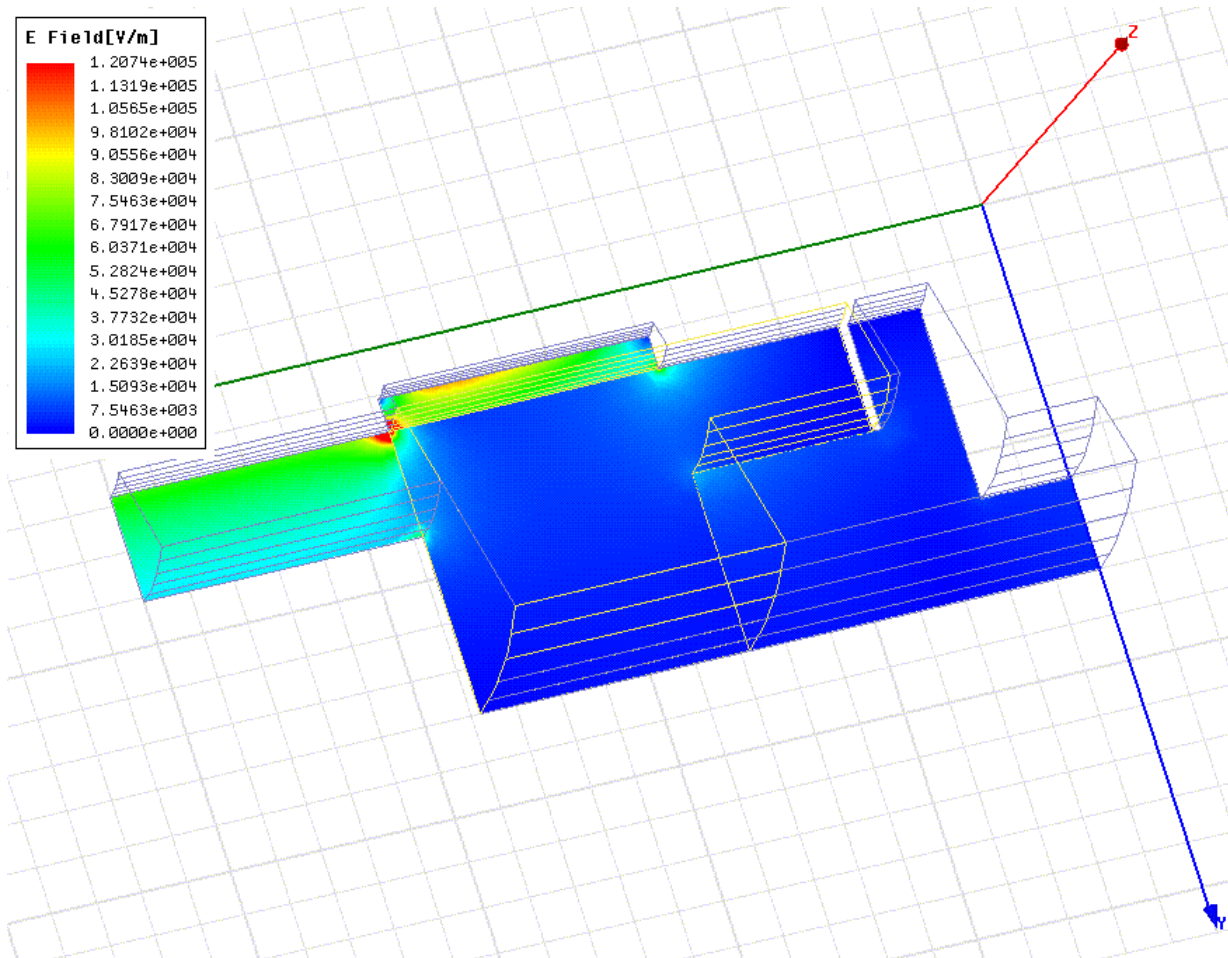
縮尺4:1



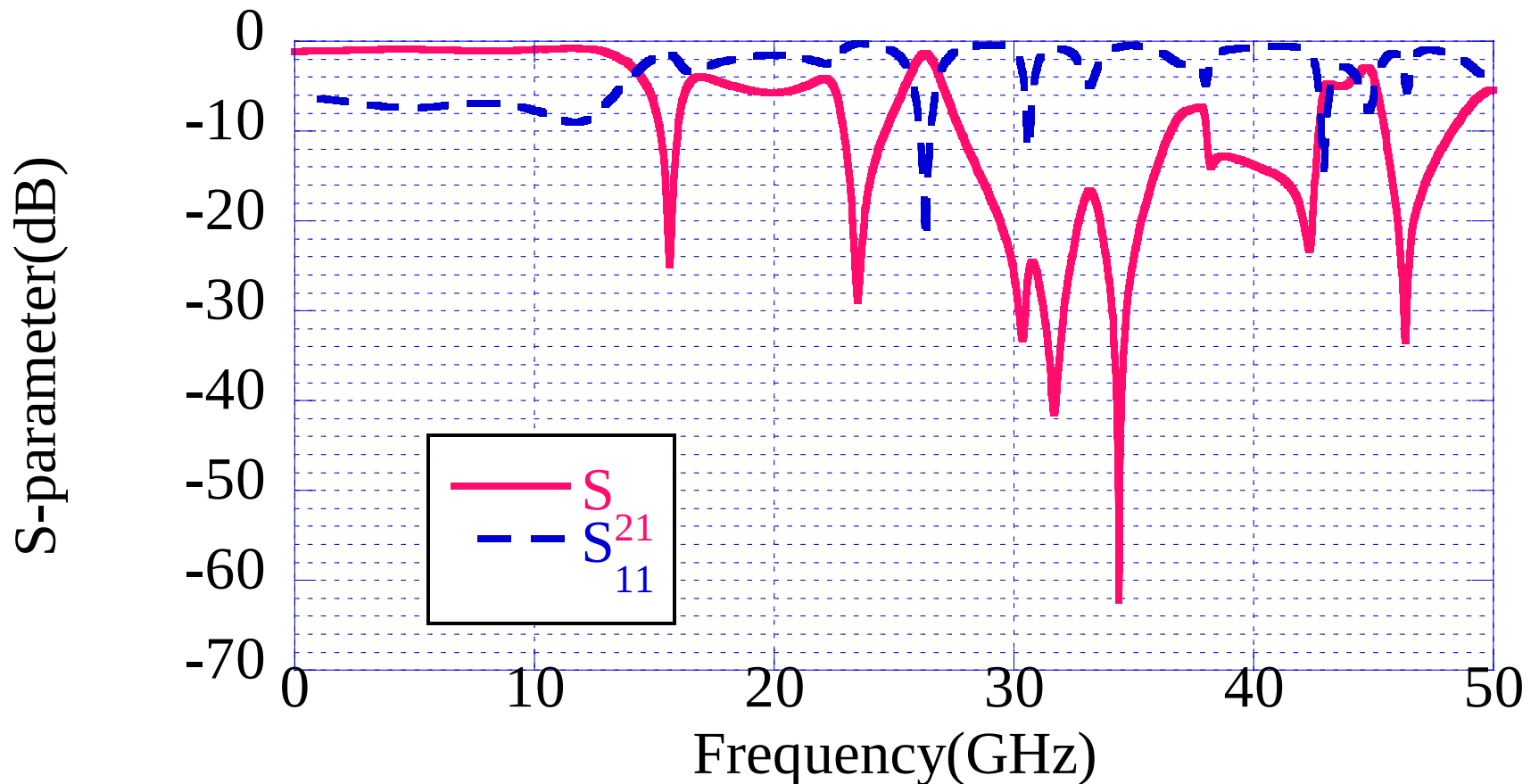
Tips

- **Using normal SMA-J connector (or N-J, too) usually encounter difficulty in RF contact at the split-pin of the center conductor due to brazing process – No spring action might be expected after the process.**
 - Using P-structure.. not easy to handle..
 - Use pin on the J-structure (“Reverse type J”)
- **Gold-plating of at the RF connector is desirable**
 - Not easy to maintain the thickness of the gold during brazing process (Gold will be diffused into the bulk metal..)

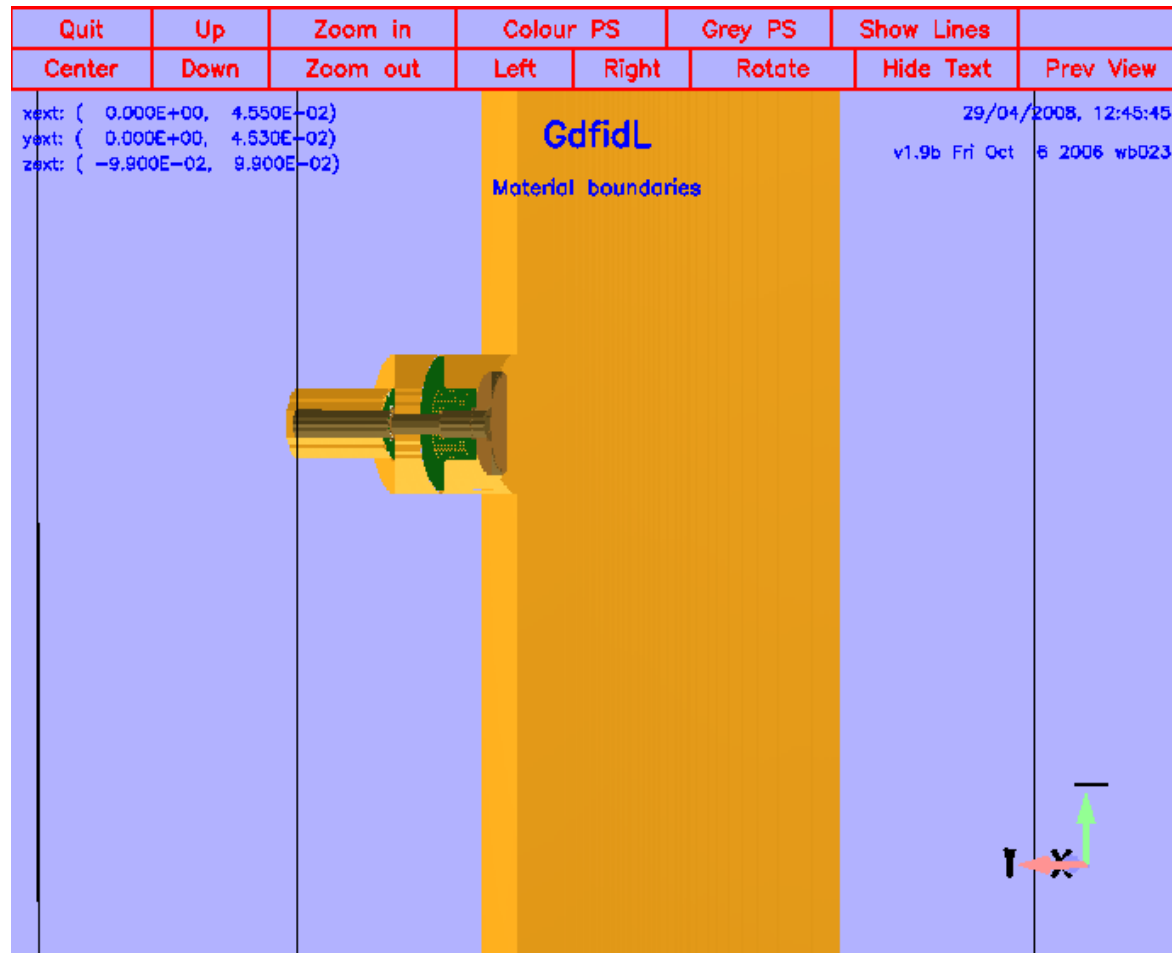
HFSS model



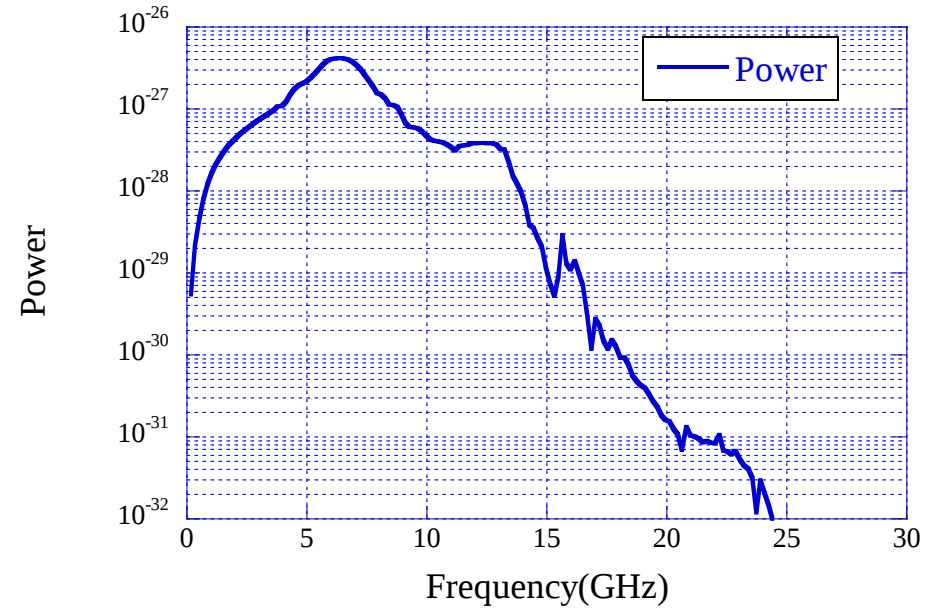
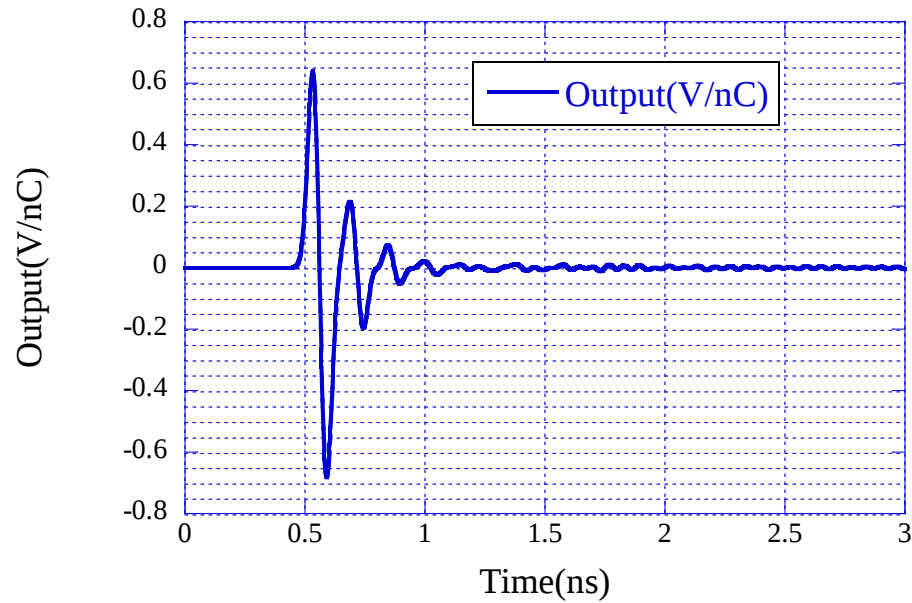
Simulated S-Parameters



GdfidL model



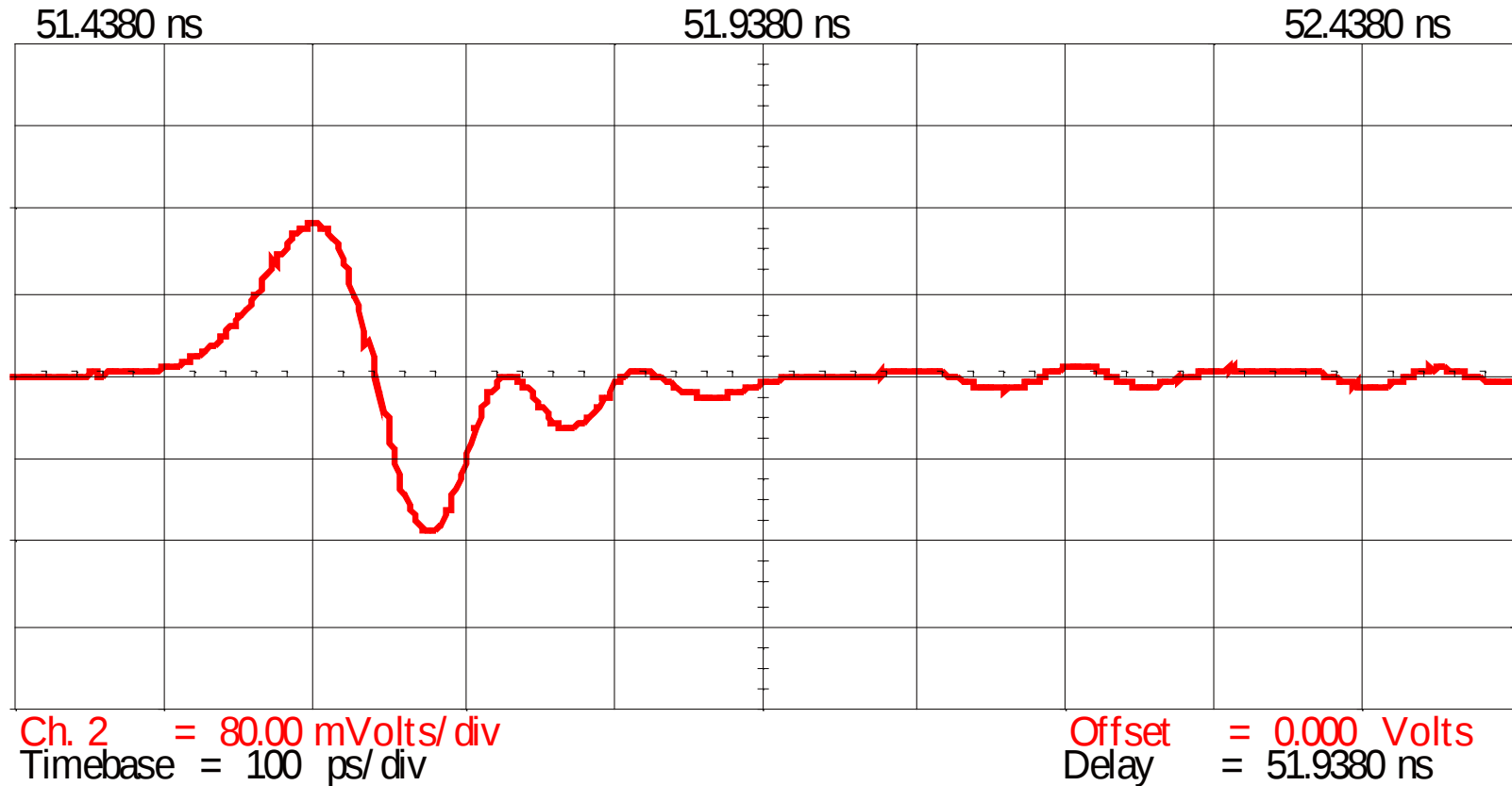
Simulated Port output



Tips

- **Need to pay attention to the possible trapped modes in the sealing structure, which may damage the seal on high beam current operation.**
 - Use Eigen-mode solver to estimate the frequency of the trapped mode.
 - Fine frequency sweep to find dip structure in S_{11}
 - Coupling to coaxial mode might be difficult.
- **Need to pay attention to the multipactoring around the button gap, especially for high single-bunch current machine.**
- **Longitudinal beam coupling impedance might not be negligible on large circumference, high beam current machine.**

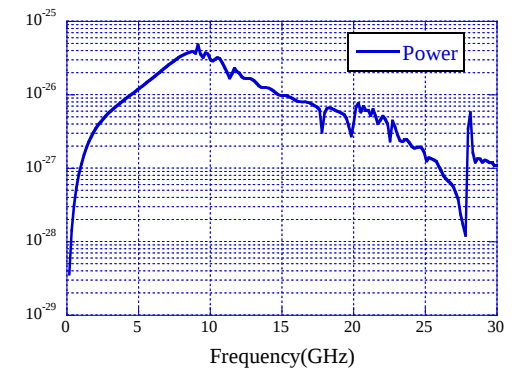
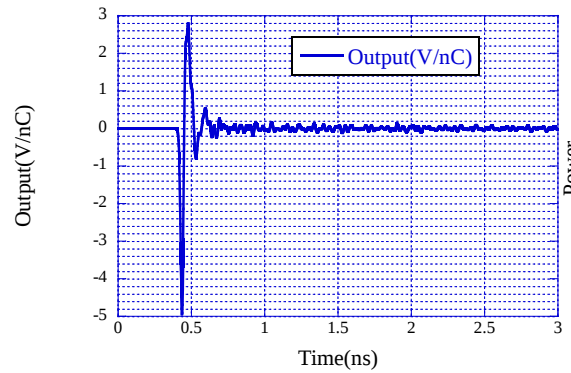
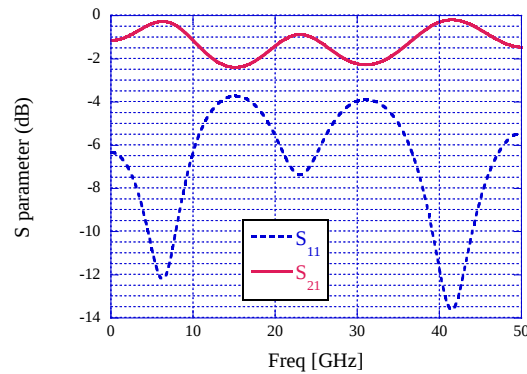
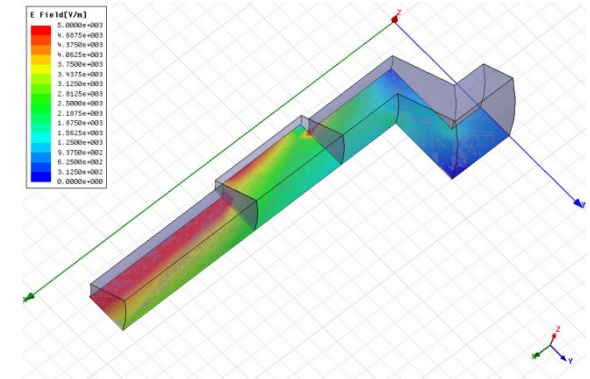
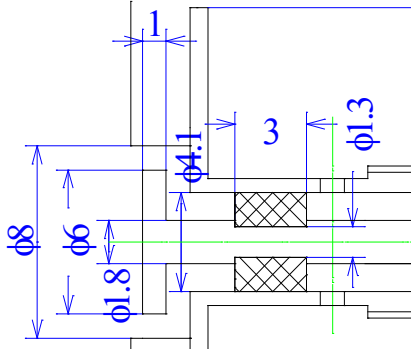
Measured signal (20GHz scope)



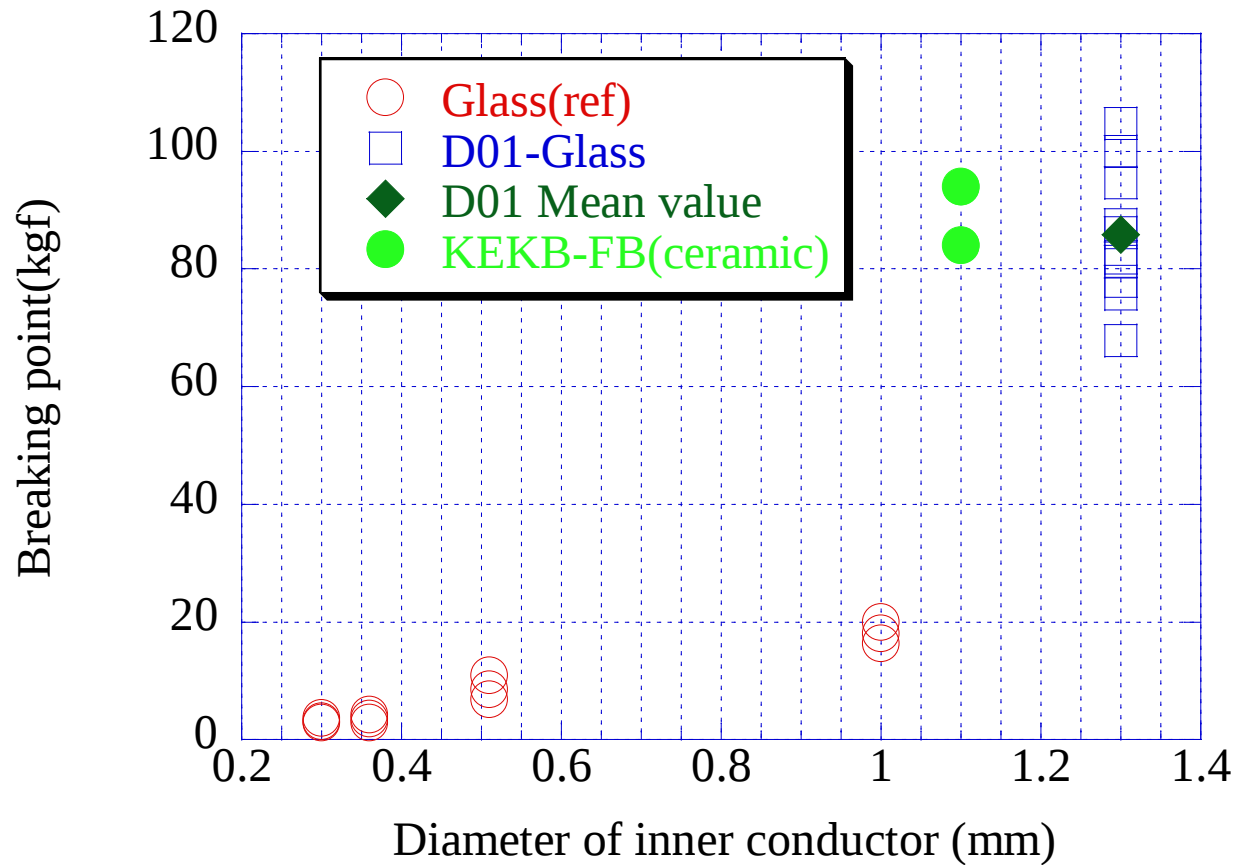
9nC/bunch LER 43dB attenuation, LER upstream

Maximum beam current at KEKB: $2A + 1.3A = 3.3A$ with large horizontal offset

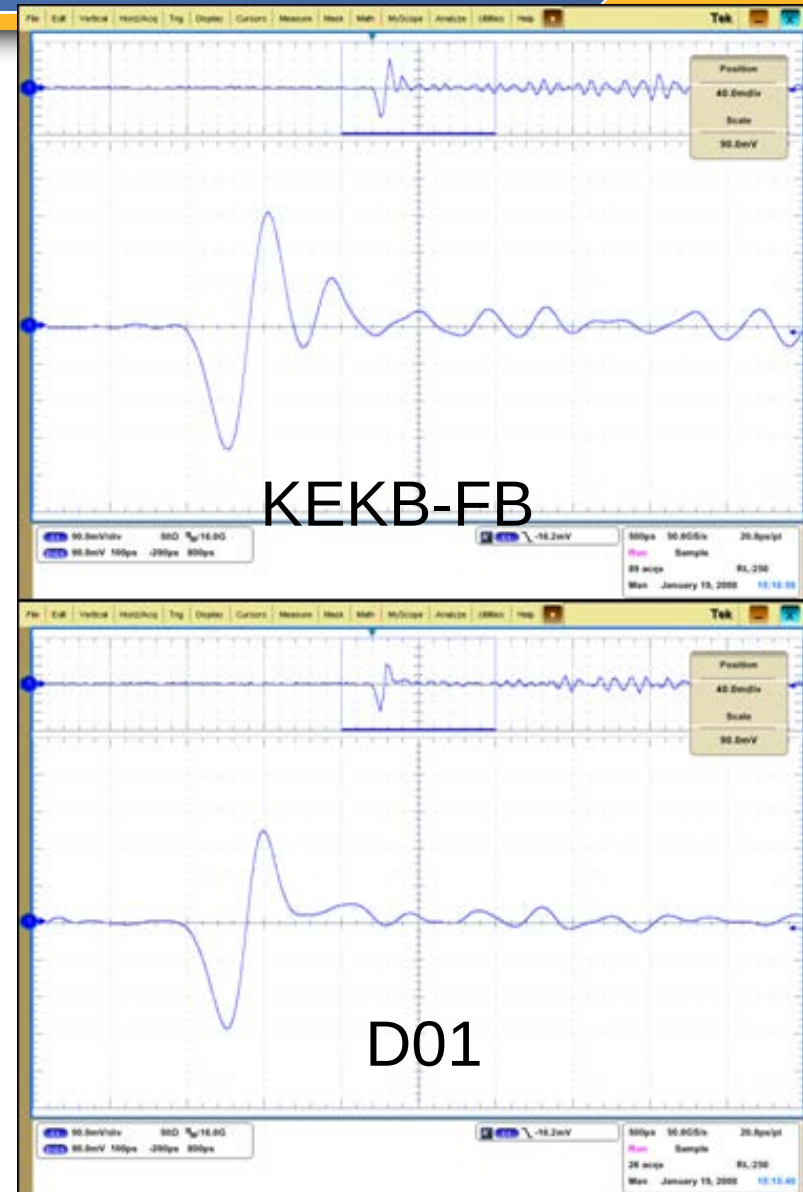
Feedthrough with low $\epsilon_r(\sim 4)$ sealing



Center pin pulling-out test

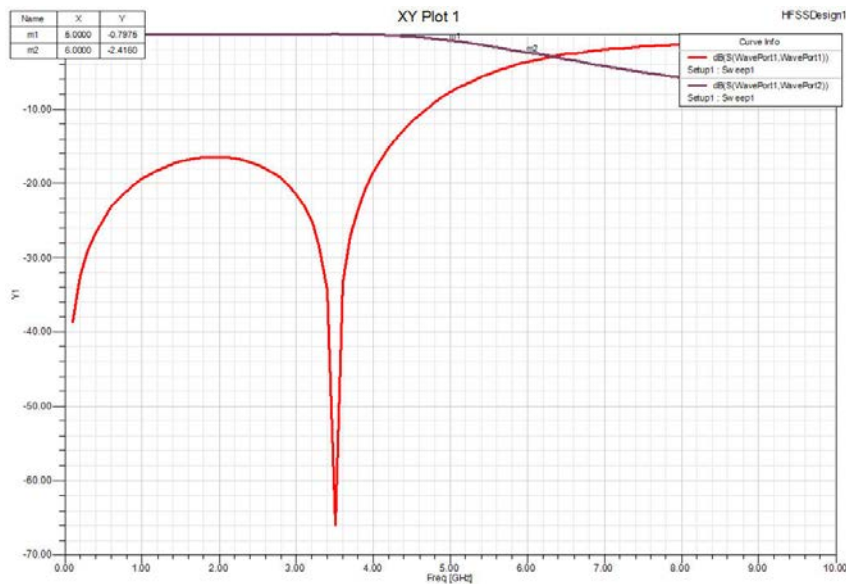


Beam test using Linac short pulse

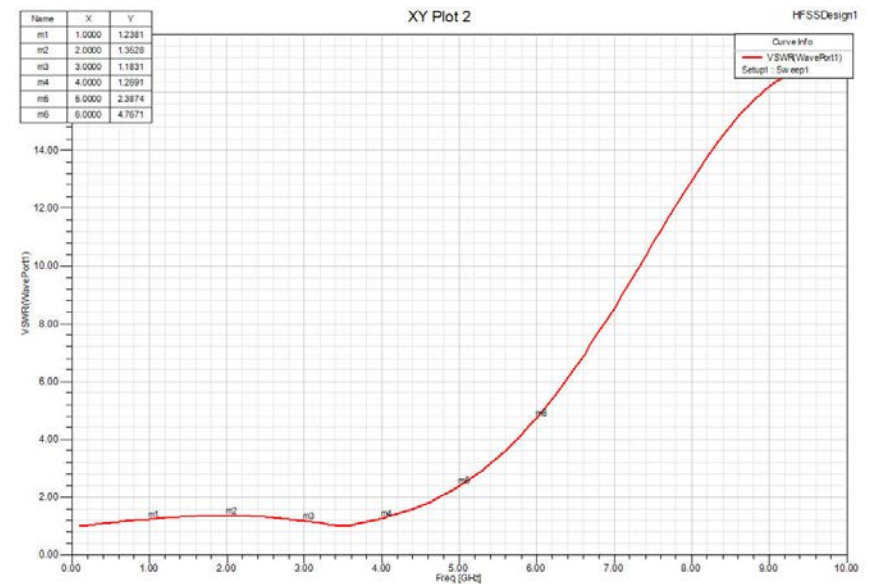


Simulated S-Parameters

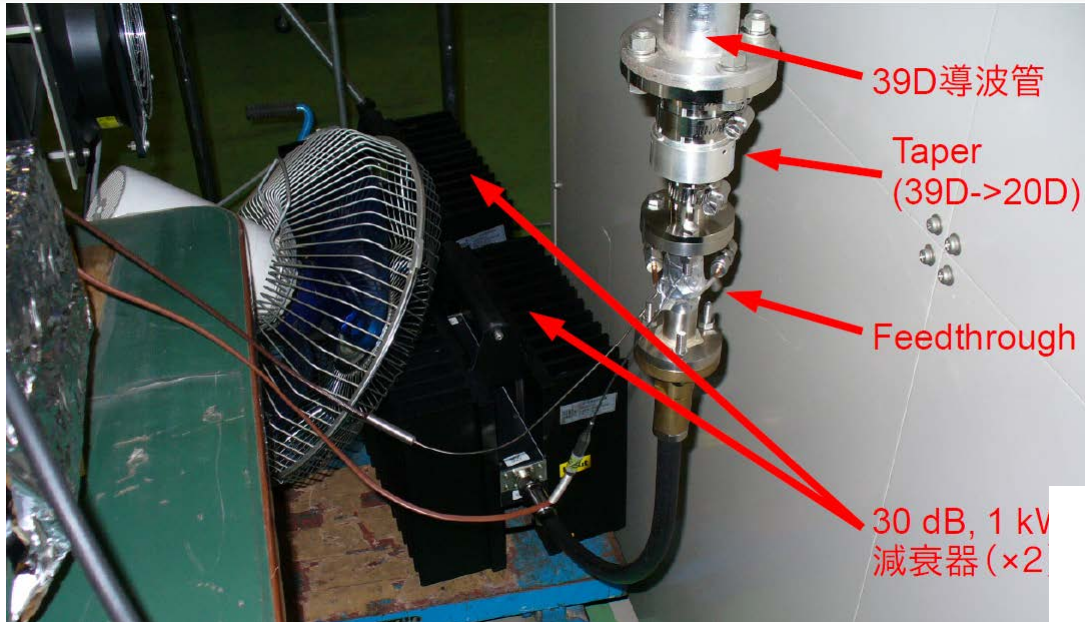
S21 and S11



VSWR(S11)



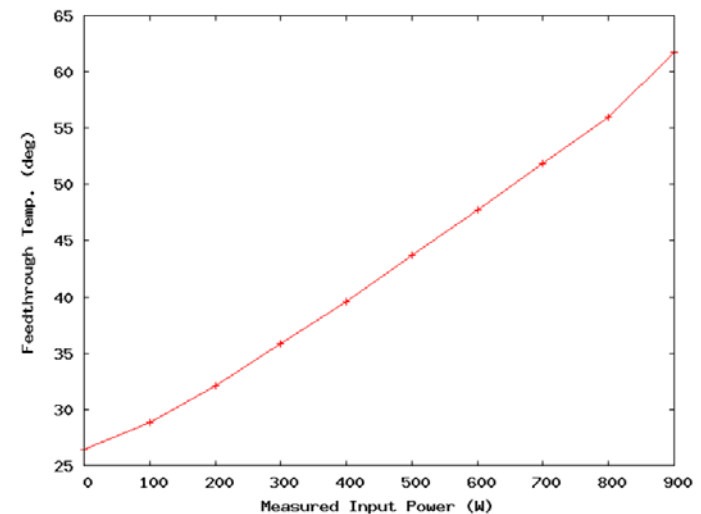
High power test



1.3GHz power source

- Temperature rise :4 deg/100W
(without water cooling)

Feedthrough温度対入力パワー



冷却水がなくても900 Wまでは異常無し。

Tips

- To enhance thermal conductivity between the center conductor and the outer wall, it might be considered to fill BN ($\epsilon_R \sim 4$) at the air side.
- Si_3N_4 has lower ϵ_R and has better (lower) loss tangent
 - Expensive
 - Mechanically weaker than alumina-ceramic

Summary

- **Briefly reviewed the transmission-line theory**
 - S-Parameters, SWR, Time-domain response
- **Introduced E-M simulation software**
 - HFSS (Frequency domain)
 - GdfidL (Time domain)
- **Shown several examples**
 - KEKB-FB button electrode
 - SuperKEKB-FB button electrode
 - High power feedthrough for SuperKEKB longitudinal kicker.

Reference

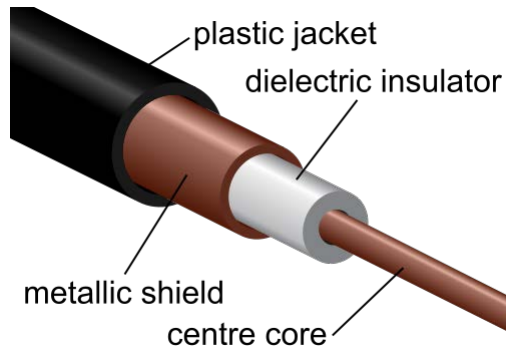
- **“Microwave Engineering Passive Circuits”,**
by Peter A. Rizzi, ISBN 0135867029
- **“Introduction to Microwave Theory”,**
by Harry A. Atwater, ISBN 0898741920
- **Ansys HFSS,**
 - <http://www.ansys.com/Products/Simulation+Technology/Electromagnetics/High-Performance+Electronic+Design/ANSYS+HFSS>
- **GdfidL, <http://www.gdfidl.de/>**
- **Kyocera Corporation**
 - <http://global.kyocera.com/prdct/fc/product/usage/vacuum/index.html>
- **Orient Microwave Corp.**
 - <http://www.orient-microwave.com/english/index.html>



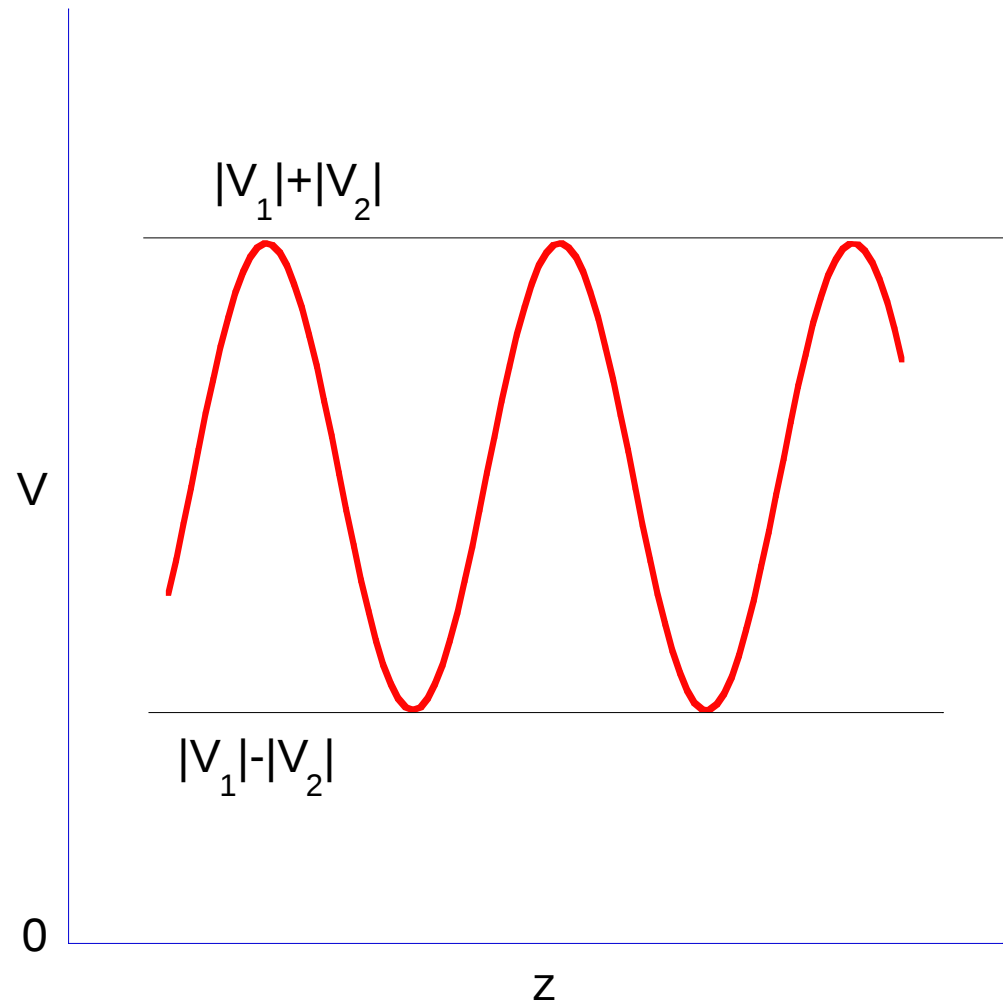
backup

Transmission line

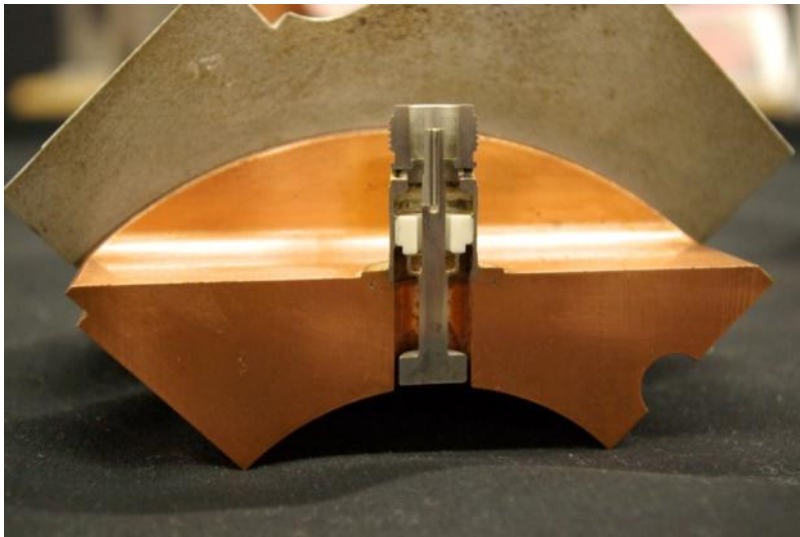
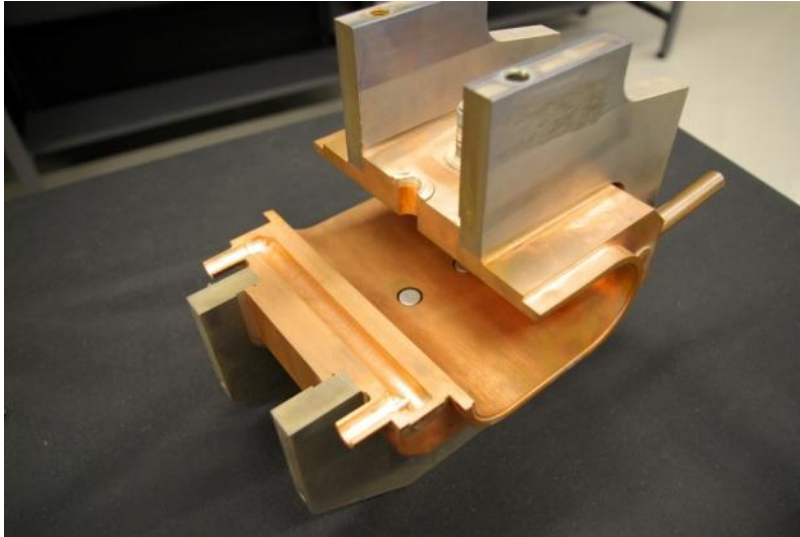
- **Coaxial cable**



Standing wave

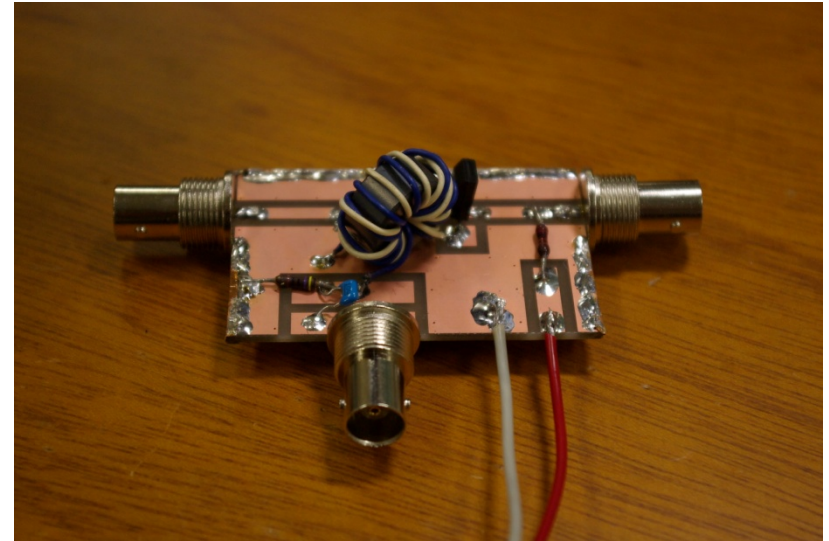
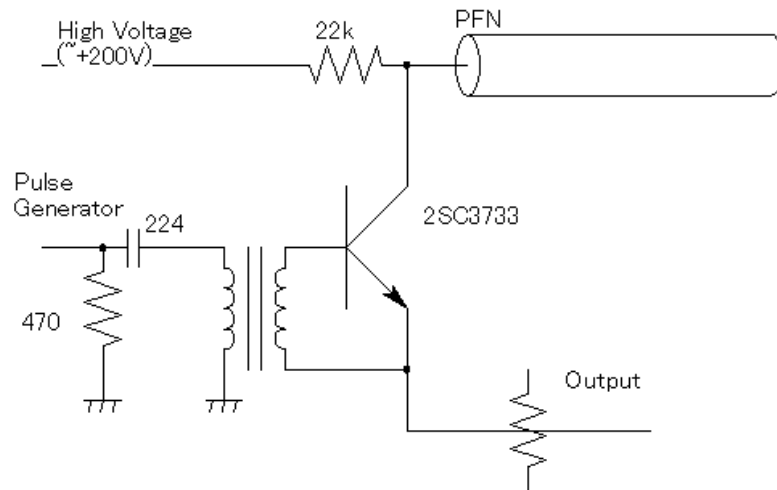


例：ボタン電極型ビーム位置モニタ

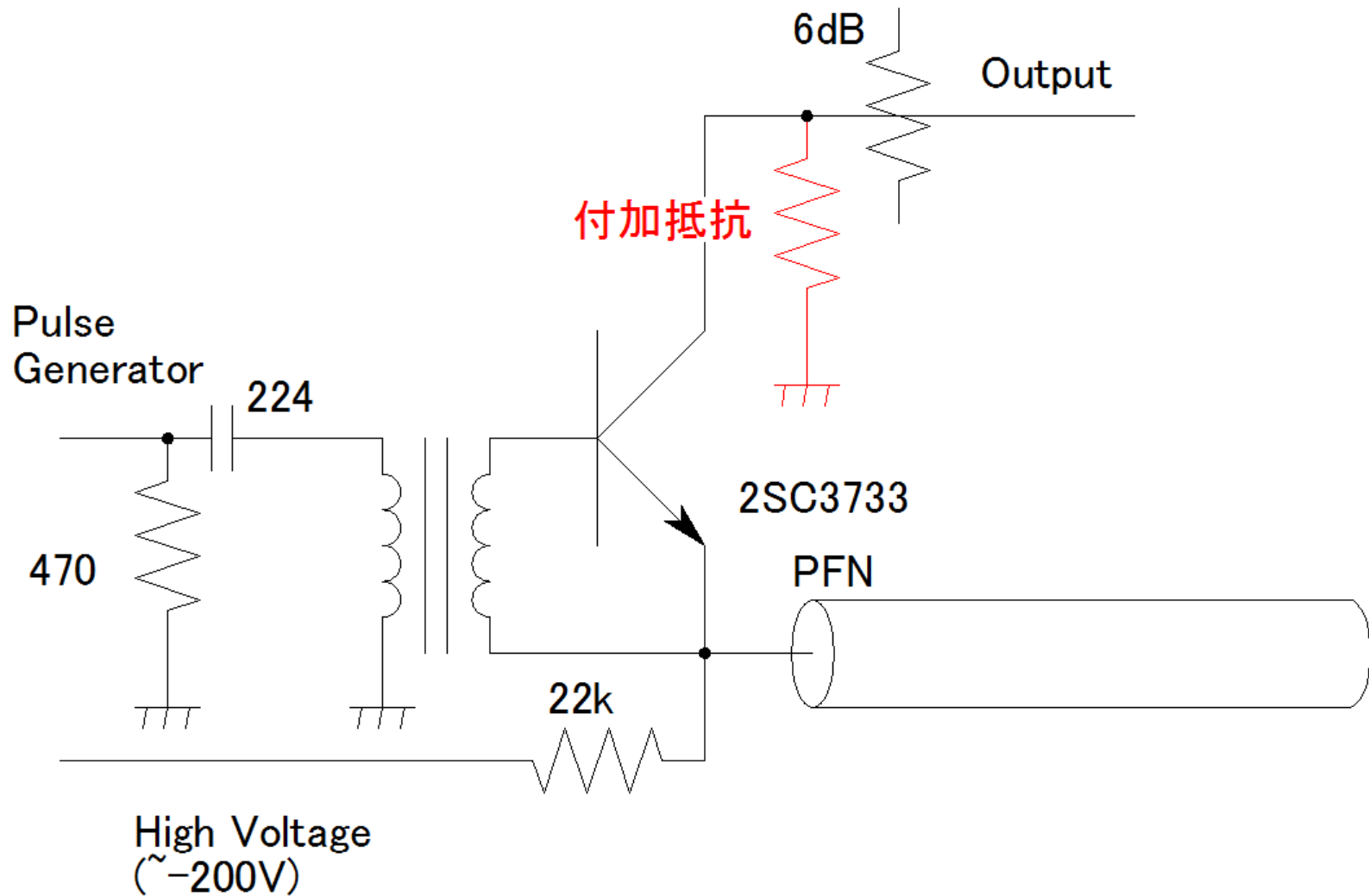


四つの電極に出てきた電荷の差から、バンチの重心位置を求めるためのモニターです。レンズの働きをする四極電磁石に固定してあります。

アバランシェランジスタパルサー(正極性)

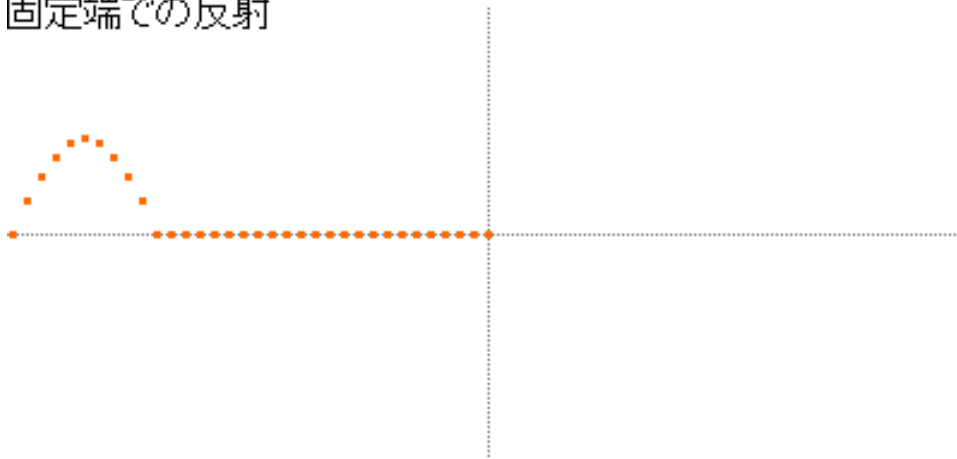


アバランシェパルサー(負極性)

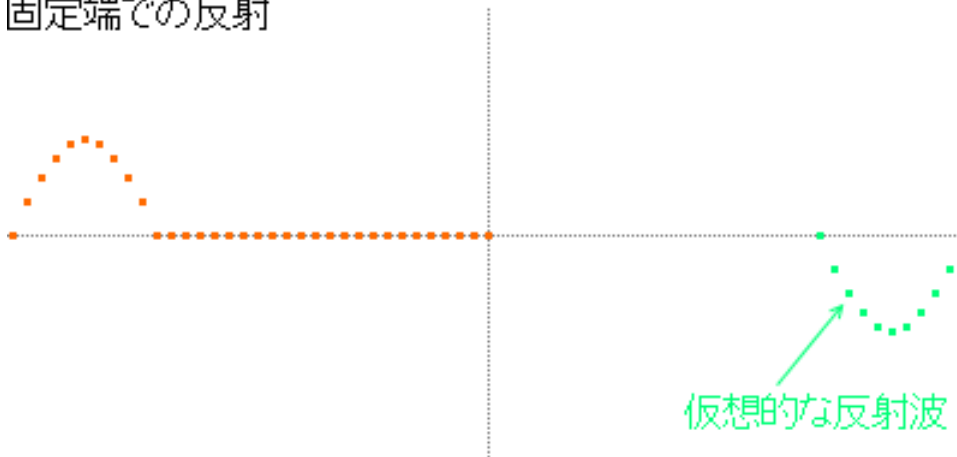


固定端での反射

固定端での反射

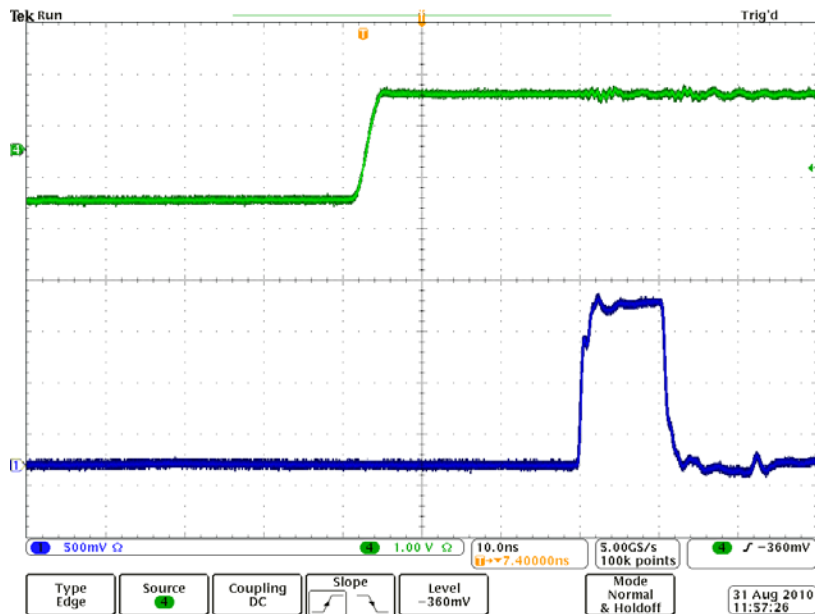


固定端での反射



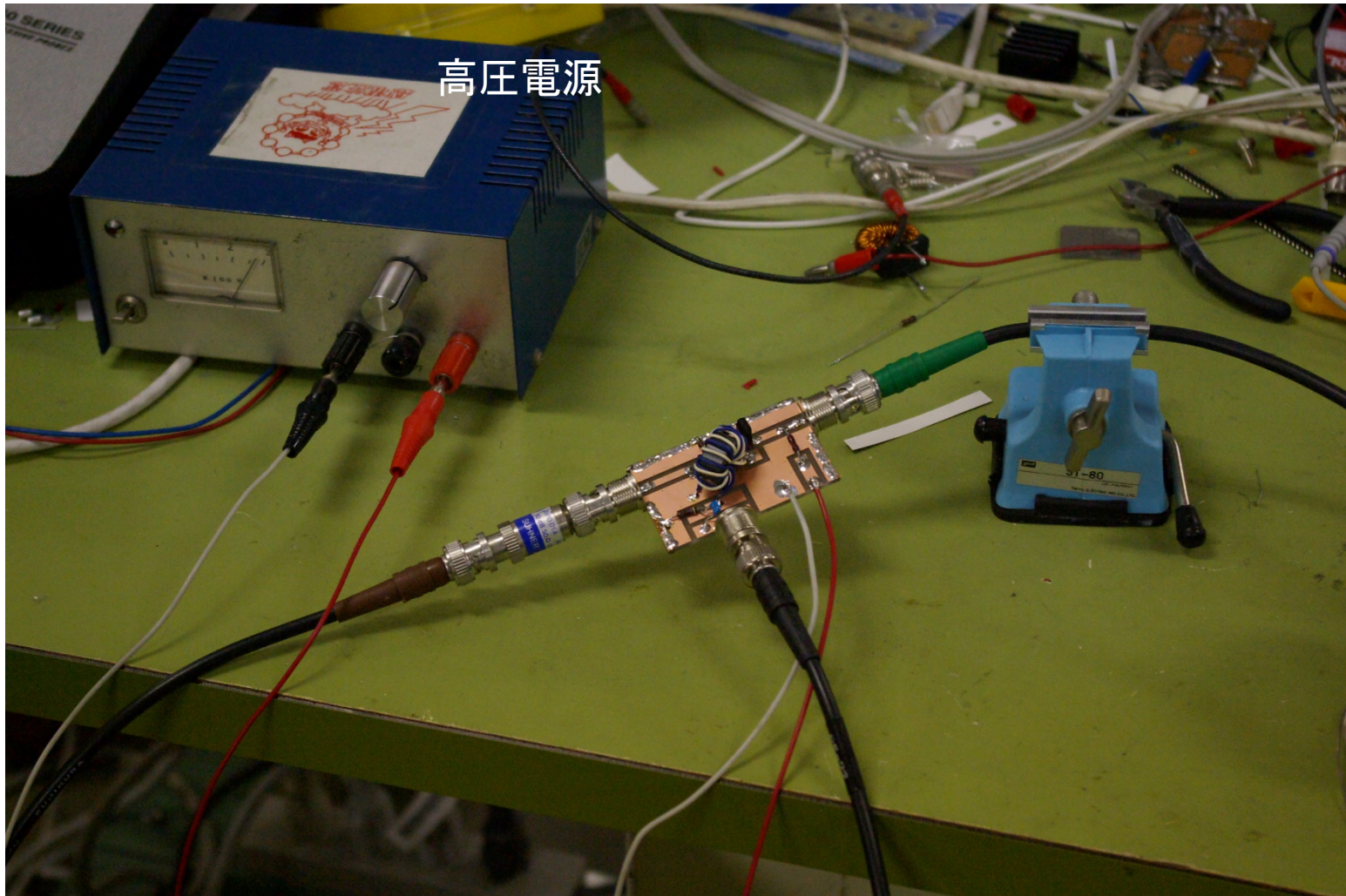
仮想的な反射波

出力は

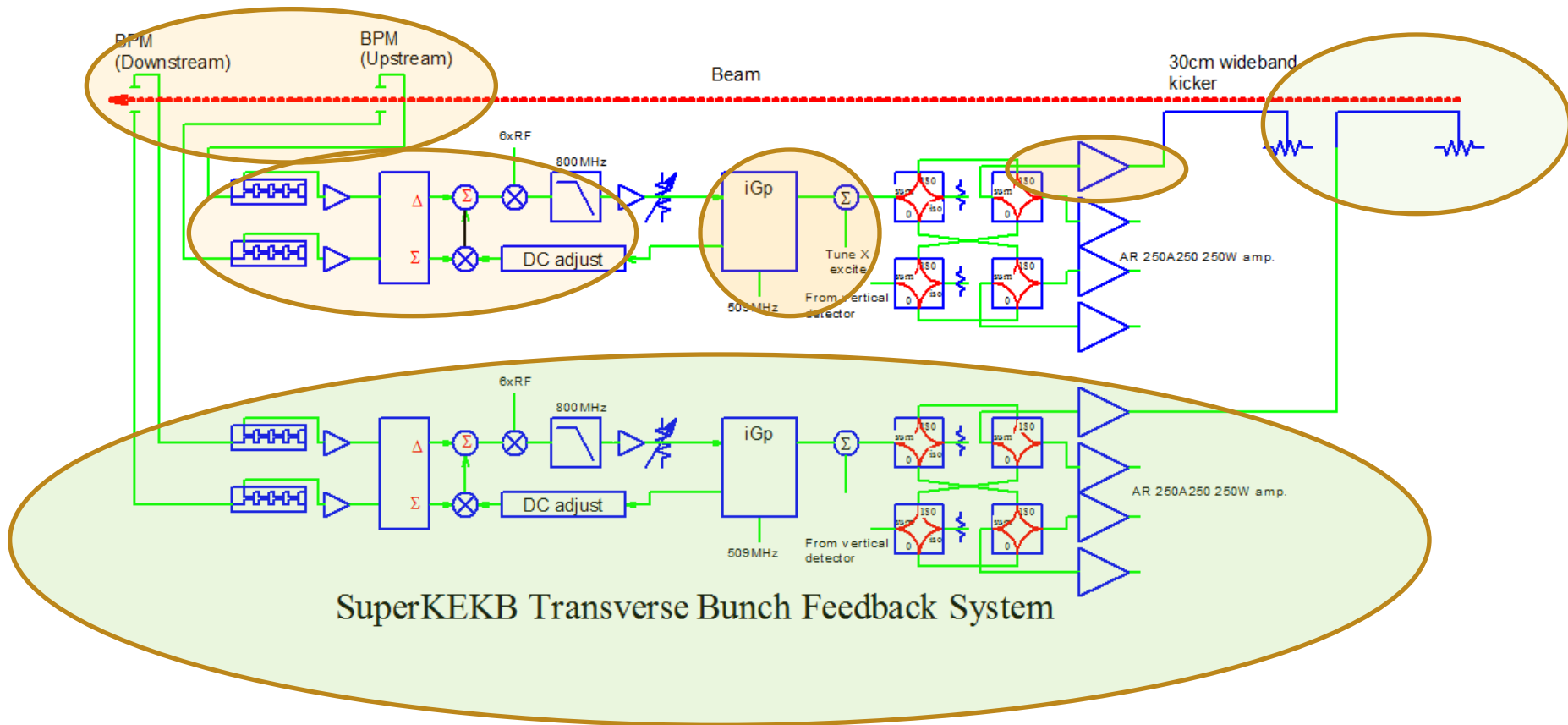


- トリガーが入ってトランジスタがONになり、約10ns後にOFFになっている。
- このとき、PFNには1mの同軸線をつけていた。ここにたまっていた高電圧が抜けて、パルス高が0に戻った。

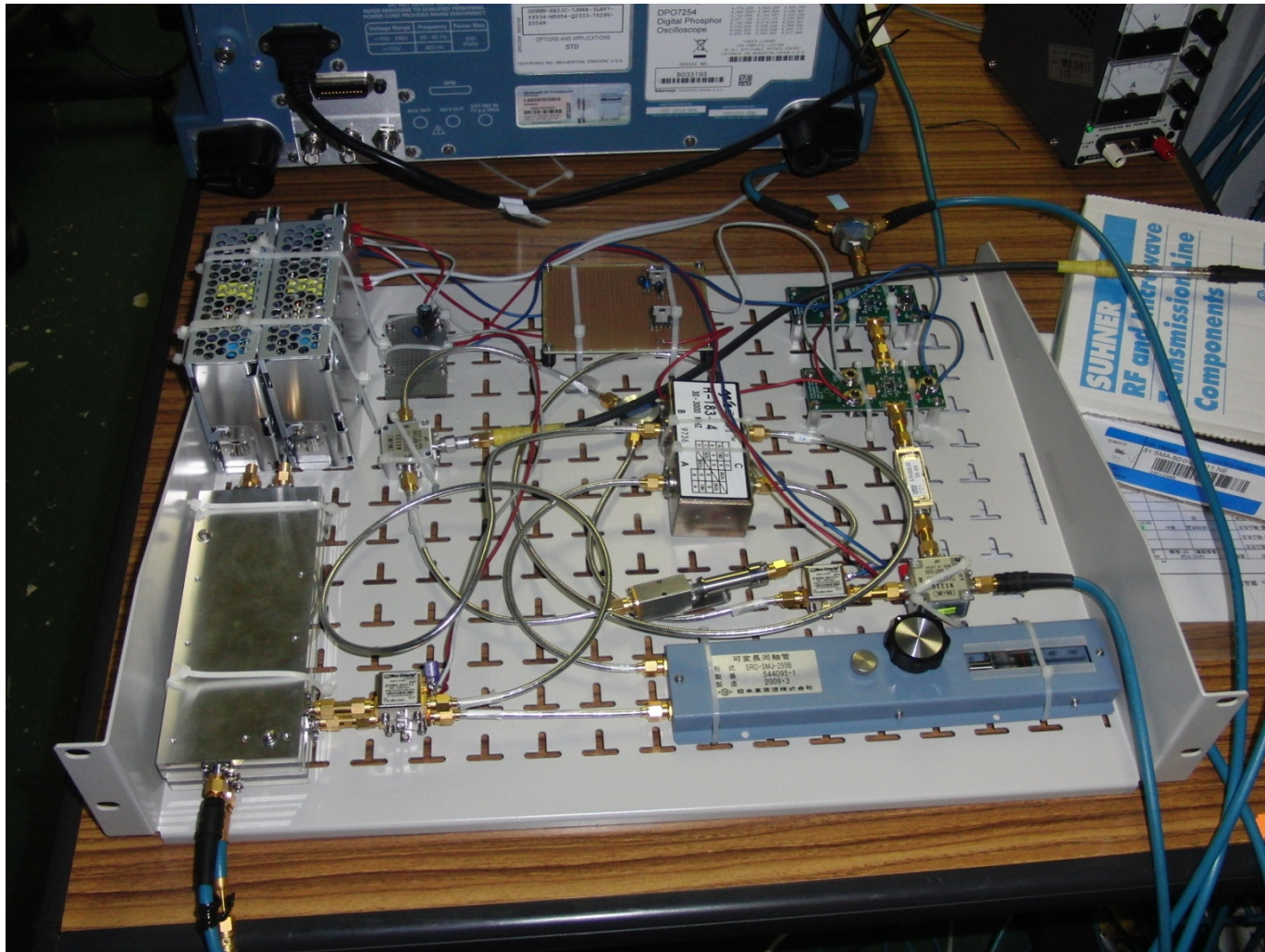
高圧電源



SuperKEKB Transverse FB plan



Bunch position detector prototype



Vacuum chamber

- Aluminum alloy antechamber
- cutoff frequency < 1 GHz

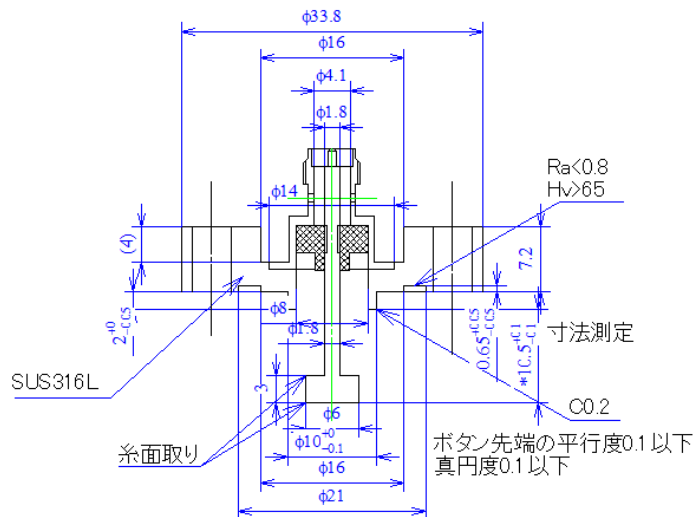
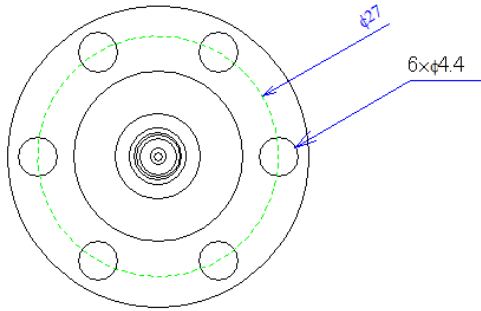
Aluminum-alloy duct



Aluminum-alloy duct



BPM head



SuperKEKB用BPM model-E1
 作図: M.Tobiyama 6/Oct/2006
 修正: M.Tobiyama 8/Nov/2006



Impedance/button output simulation

